

# Instruction Manual **ZEISS Crossbeam 550L, Crossbeam 550**

Focused Ion Beam - Scanning Electron Microscope (FIB-SEM)



#### ZEISS Crossbeam 550L, Crossbeam 550

Original Manual

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Glossary ZEISS

# **Glossary**

#### aBSD

Annular Backscattered Flectron Detector

#### **AIC**

Ampere Interrupting Capacity

## **Aperture**

Mechanical limitation of an opening oriented perpendicular to the optical axis, which filters out electrons whose trajectories (tracks) do not run close to the optical axis.

#### **aSTEM**

Annular Scanning Transmission Electron Microscopy

# **Astigmatism**

Lens aberration that distorts the shape of the electron beam, compensated by the stigmator.

#### **Backscattered electrons**

High-energy electrons that are liberated from the specimen surface when the specimen is hit by the primary electron beam.

#### **Bakeout**

Degassing of surfaces of a vacuum system by heating during the pumping process.

#### Beam booster

Anode and liner tube of the Gemini column are connected mechanically and electrically forming the beam booster. A booster voltage (UB, liner voltage) of +8 kV is applied to the beam booster, so that a high beam energy is maintained throughout the entire column. The beam booster technique has two main advantages: It minimizes beam widening, that may occur due to stochastic electronelectron interactions. Consequently there is almost no loss in beam brightness, even at low acceleration voltages. Secondly, the beam booster technique enhances protection against external stray fields.

#### **BSD**

Backscattered Electron Detector

#### **BSE**

Backscattered Electron

#### CAN

Controller Area Network

#### CCD

Charge-Coupled Device

#### CL

Cathodoluminescence

#### Condenser

Device that collects and focuses the electron beam onto the specimen.

#### D

Depth

#### **DECT**

Digital Enhanced Cordless Telecommunications

#### **EBSD**

**Electron Backscatter Diffraction** 

#### EC

**European Community** 

# **EDS**

Energy Dispersive X-ray Spectroscopy

#### **EDX**

Energy Dispersive X-ray Spectroscopy

#### **EHT**

Extra High Tension

#### **EIGA**

European Industrial Gases Association

# ΕM

Electron Microscope

#### EM server

A server that implements the internal communication between control software and microscope hardware.

ZEISS Glossary

#### **EMC**

Electromagnetic Compatibility

#### **EMO**

**Emergency Off** 

#### **EsB**

Energy-selective Backscattered

#### **Eucentric**

Type of stage, the rotation axes of which intersect in the same point. The specimen surface is located in the eucentric point, where the tilt axis meets the beam axis. This guarantees that the focus is maintained when the specimen is tilted at a certain working distance.

#### **Extractor**

Positive electrode that attracts electrons from the filament.

#### Faraday cup

Small insulated metal container, equipped with an aperture where electrons can enter but not escape. Used to measure the specimen current in the microscope.

#### **FESEM**

Field Emission Scanning Electron Microscope

#### **FIB**

Focused Ion Beam

# Focus wobble

Function that sweeps the focus of the objective lens backwards and forward through the focus on the specimen plane. When the aperture is misaligned a lateral shift is observed.

# FTP

File Transfer Protocol

#### GIS

Gas Injection System

## GUI

Graphical User Interface

#### Н

Height

#### IGC

Industrial Gases Council

#### **IGP**

Ion Getter Pump

#### IR

Infrared

#### LOTO

Lockout/Tagout

#### M

M-axis

#### **MSDS**

Material Safety Data Sheet

#### PC

Personal Computer

#### PE

Protective Earth (ground)

#### PΕ

**Primary Electron** 

# Penning gauge

Device for measuring high vacuum in the vacuum system.

# Pre-vacuum pump

A pump for generating a pre-vacuum.

#### Primary electron beam

Narrowly bundled beam of accelerated electrons that hit the specimen surface.

# R

R-axis (Rotation)

#### RF

Radio Frequency

#### RMS

Root Mean Square

#### Schottky field emitter

Type of electron source in which emission occurs at or near the work function barrier.

Glossary ZEISS

#### **Scintillator**

Substance that absorbs electrons and in response, fluoresces photons while releasing the previously absorbed energy.

#### SE

Secondary Electron

#### **Secondary electrons**

Low-energy electrons that are emitted from the specimen surface when the specimen is hit by the primary electron beam. Secondary electrons are generated by inelastic scattering.

#### **SEM**

Scanning Electron Microscope

#### **SEMI**



Semiconductor Equipment and Materials International (SEMI) is a industry association comprising companies involved in the electronics design and manufacturing supply chain.

#### **SESI**

Secondary Electron Secondary Ion

# SIMS

Secondary Ion Mass Spectrometry

#### **STEM**

Scanning Transmission Electron Microscope

# Stigmator

Compensates astigmatism (lens aberration), so that the electron beam becomes rotationally symmetrical.

# Suppressor

Electrode (anode) that suppresses unwanted thermionic emission from the shank of the Schottky field emitter.

#### Т

T-axis (Tilt)

#### TEM

Transmission Electron Microscope

#### U

Voltage

#### User

Person examining a sample under the microscope.

#### W

Width

#### WD

Working Distance

#### **WDS**

Wavelength Dispersive X-ray Spectroscopy

#### **WDX**

Wavelength Dispersive X-ray Spectroscopy

# WEEE

Waste Electrical and Electronic Equipment

#### Χ

X-axis

#### XeF<sub>2</sub> precursor

Xenon difluoride precursor

#### X-ray

Type of high energy electromagnetic radiation, that is generated during the operation of electron microscopes.

#### Υ

Y-axis

#### Z

Z-axis

#### **ZEISS Sales & Servicepartner**

The sales and servicepartner is generally in the field for customer support in a regional area and / or a clearly defined customer group.

# 1 General Information

This manual is part of the SEM workstation, hereinafter referred to as the "microscope". Read the instructions carefully. Keep the manual nearby the microscope and hand it over to future owners of the microscope.

The manual is designed for operators who have been trained to operate the microscope by a ZEISS service representative. Basic operator training and safety instructions will be provided within the scope of initial start-up by ZEISS. Operators of the microscope must not deviate from the instructions provided in this manual.

This manual contains the following chapters:

Chapter	Content
Glossary	Lists important technical terms.
General Information	Explains the function and structure of this manual.
Safety	Summarizes important safety details.
Device Description	Describes the microscope and its main hardware components.
Software Description	Provides an overview of the user interface.
Installation	Refers to the ZEISS service representatives.
Operation	Contains information about starting the microscope and the software, obtaining a first image, adjusting important parameters, and powering down the microscope, also in emergency.
Maintenance and Repair	Informs you about preventive maintenance work and intervals and the change of consumables.
Troubleshooting	Describes common issues and how to resolve them.
Shutdown and Disposal	Summarizes notes on shutdown and disposal.
Technical Data and Conformity	Lists hardware specifications as well as the manufacturer's declaration that the equipment is in conformity with all applicable European Directives.
Parts and Tools	Lists consumables, spare parts, tools, and accessories.
Abbreviations	Lists abbreviations used in this manual.
Index	Lists keywords to help you find relevant information quickly.

# 1.1 Text Conventions and Link Types

The following text conventions and link types are used:

Text convention	Meaning
Click <b>Start</b> .  Press the <b>STANDBY</b> button.  Press <b>[Enter]</b> on the keyboard.	The names of controls and important information are shown in bold letters.
Press <b><ctrl+alt+del></ctrl+alt+del></b>	Press several keys on the keyboard simultaneously.

Text convention	Meaning	
Select <b>Tools &gt; Goto Control Panel &gt; Air-lock</b> .	Follow a path in the software.	
Text input Text output	<ul><li>Text to be entered by the user</li><li>Text displayed by the system</li></ul>	
Programming and Macros	Anything typed in literally during programming, including, for example, macro codes, keywords, data types, method names, variables, class names, and interface names.	

Tab. 1: Text convention

Link type	Meaning
See: Text Conventions and Link Types [▶ 9].	Link to further information for this topic.
https://www.zeiss.com/corporate/int/ home.html	Link to a website on the internet.

Tab. 2: Link types

# 1.2 Explanation on Warnings and Additional Information

DANGER, WARNING, CAUTION, and NOTICE are standard signal words used to determine the levels of hazards and risks of personal injury and property damage. Not only the safety instructions and warnings in the **Safety** chapter are to be considered but also the safety instructions and warnings in other chapters. Failure to comply with these instructions and warnings can result in both personal injury and property damage and involve the loss of any claims for damages.

The following symbols and warnings indicating dangerous situations and hazards are used in this document.

# **A** DANGER

# Type and source of danger

DANGER indicates an imminently hazardous situation which, if not avoided, will result in death or serious injury.

# **MARNING**

#### Type and source of danger

WARNING indicates a potentially hazardous situation which, if not avoided, may result in death or serious injury.

# **⚠** CAUTION

# Type and source of danger

CAUTION indicates a potentially hazardous situation which, if not avoided, may result in minor or moderate injury.

# **NOTICE**

# Type and source of danger

NOTICE indicates a potentially harmful situation which, if not avoided, may result in property damage.

#### Info

Provides additional information or explanations to help users better understand the contents of this Instruction Manual.

# 1.3 Further Applicable Documents

#### **SmartSEM Software Manual**

For detailed information on how to use the SmartSEM software for imaging and hardware control, refer to the SmartSEM software manual.

#### **SmartFIB Software Manual**

For detailed information on how to use the SmartFIB software for ion beam exposure, refer to the SmartFIB software manual.

#### **Instruction Manual for Options**

For detailed information regarding optional accessories, refer to the respective instruction manual in your document folder.

#### **Product Specification and Installation Requirements**

For details on technical data, refer to the documents Product Specification and Installation Requirements.

# **Material Safety Data Sheets**

Material safety data sheets (MSDS) of chemicals used in combination with the microscope are contained in the document folder delivered with the microscope.

# 1.4 Contact

If you have any questions or problems, please contact your local ZEISS Sales & Servicepartner or one of the following addresses:

# Headquarter

Phone:	+49 1803 33 63 34
Fax:	+49 3641 64 3439
Email:	info.microscopy.de@zeiss.com

# **Service Germany**

Phone:	+49 7364 20 3800
Fax:	+49 7364 20 3226
Email:	service.microscopy.de@zeiss.com

# **Courses and training**

Email: cou	rses.microscopy.de@zeiss.com
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# **ZEISS Sales & Servicepartner**

You can find a ZEISS Sales & Servicepartner in your area under <a href="https://www.zeiss.de/mikroskopie/website/forms/sales-and-service-contacts.html">https://www.zeiss.de/mikroskopie/website/forms/sales-and-service-contacts.html</a>.

ZEISS 2 Safety | 2.1 Intended Use

# 2 Safety

This chapter contains general requirements for safe working practices. Any person using the Microscope System or commissioned with installation or maintenance must read and observe these general safety instructions. Knowledge on basic safety instructions and requirements is a precondition for safe and fault-free operation. Operational safety of the supplied Microscope System is only ensured if it is operated according to its intended use.

If any work is associated with residual risks, this is mentioned in the relevant parts of this document in a specific note. When components must be handled with special caution, they are marked with a warning label. These warnings must always be observed.

# 2.1 Intended Use

The microscope has been designed to generate an image or to analyze appropriate specimens, which is achieved by scanning a focused electron or ion beam across the specimen.

In addition to microscopic examination, the microscope also allows for the modification of appropriate specimens. For these purposes, the specimen is placed in the evacuated specimen chamber.

The microscope has been designed for the following applications:

#### Imaging

Image generation and specimen analysis can be performed by means of a focused electron beam (SEM Imaging) or a focused ion beam (FIB Imaging) that is scanned across the specimen.

This application allows for the analysis of surface structures and near-surface structures of appropriate specimens.

#### Milling

Milling comprises all applications that include material removal from the specimen surface by a focused ion beam.

In combination with a gas injection system option, the microscope has been designed for the following applications:

#### Gas-assisted deposition

A process gas in combination with either a focused electron beam or a focused ion beam can be used to deposit material onto the specimen surface.

#### Gas-assisted etching

This application enables an accelerated material removal by a focused electron beam or a focused ion beam in combination with a process gas.

#### Info

Not for therapeutic, treatment or medical diagnostic evidence.

#### Info

Not all products are available in every country. Contact your local ZEISS representative for more information.

#### **SmartSEM Software**

The SmartSEM software is intended for the operation of scanning electron microscopes (SEMs).

The SmartSEM software has to be run exclusively on a personal computer delivered by ZEISS. Any other applications are not allowed.

Regarding the operation of the microscope, the following regulations must be met:

• Only operate the microscope according to the operating conditions after correct installation by a ZEISS service representative.

- The microscope is only to be used by operators who have been trained by a ZEISS service representative. Basic operator training and safety instructions will be provided within the scope of the initial start-up by ZEISS. Make sure that everyone who operates the microscope only performs the tasks for which he/she is trained.
- Operators of the microscope must not deviate from the instructions provided in this manual.
- Only perform preventive maintenance tasks described in this manual. All tasks of maintenance, service, and repair not described in this manual have to be performed by an authorized ZEISS service representative.
- The microscope is to be used in a laboratory environment for commercial and scientific purposes only.

Using the microscope for any other purpose is not allowed and can be hazardous.

# 2.2 Safety Procedures

#### 2.2.1 Safe Operation Conditions

If the product safety labels are covered or worn or if any of the safety devices are not in proper working condition, operation of the microscope can be hazardous.

- Periodically check the function of safety equipment.
- Periodically check that all protective cover panels are installed.
- Always follow the instructions given on the safety labels.
- Inspect and clean the product safety labels to maintain good legibility.

# 2.2.2 Requirements for Personnel

Deviating from the instructions given in this manual and on the safety labels can be hazardous or can lead to property damage.

- Do not operate the microscope until you have completely read and understood the entire user documentation delivered with the microscope.
- Observe all safety labels on the microscope and within this manual.
- Only operate the microscope according to the operating conditions after correct installation by a ZEISS service representative.
- Only ZEISS service representatives, who have specialized knowledge of radiation protection, are permitted to service the microscope.

## **Operator Training**

Within the scope of initial start-up, the ZEISS service representative will perform a basic operator training. The basic operator training consists of fundamental operation procedures including safety instructions. Besides, an introduction to basic maintenance tasks will be given for an advanced operator, who has to be an electrically skilled person. The training performed must be documented appropriately.

Special application training is offered on request.

#### 2.2.3 Preventive Maintenance

Deviating from the maintenance and repair tasks described in this manual can be hazardous or can lead to property damage.

- Only perform preventive maintenance and repair tasks described in this manual.
- All tasks of maintenance, service, and repair not described in this manual have to be performed by an authorized ZEISS service representative.

To maintain best performance of the microscope, it is essential to perform preventive maintenance on a regular basis. Moreover, it is recommended that you conclude a service contract with your local ZEISS service representative or organization.

# 2.2.4 Safe Handling of Spare Parts

Using spare parts that are not provided by ZEISS can be hazardous or can lead to property damage:

- Only genuine parts supplied by ZEISS are to be used in servicing the microscope.
- Contact your ZEISS service representative for information regarding how to order spare parts.
- Unless authorized by ZEISS, all spare parts should be installed by a ZEISS service representa-

#### 2.3 Prevention of Hazards

This section summarizes potential hazards and recommended safety precautions. Failure to follow the safety instructions and instructions may result in personal injury and property damage.

#### 2.3.1 Biological Hazards

Danger to life: Biological substances

Biological substances may pose a threat to the health of humans and other living organisms.

Keep a logbook of the biological substances loaded into the microscope and show it to the ZEISS service representatives before they perform any work on the microscope.

#### 2.3.2 Burn Hazards

surfaces during bakeout

Risk of property Parts of the enclosure in the upper range of the column may become hot during bakeout, particudamage: Hot larly after a long bakeout cycle.

- Do not place any combustible objects on the grids of the electron optical column during bake-
- After the bakeout procedure, let surfaces cool down before working around the column.
- Only advanced operators are allowed to perform the bakeout procedure.

#### 2.3.3 Chemical Hazards

Aggressive or toxic chemicals

**Risk of injury:** Aggressive or toxic chemicals can cause chemical burns.

- When handling aggressive or toxic chemicals, wear suitable protective clothing, gloves, and eye/face protection.
- Do not eat, drink, or smoke while handling toxic chemicals.
- Refer to local safety regulations.
- Read and follow the instructions in the material safety data sheet of the chemical. The material safety data sheet can be obtained from the supplier of the chemicals.

# **Reaction products**

Risk of injury: Dangerous reaction products can be present in the specimen chamber during or after operation.

- Ensure that there is an appropriate exhaust gas line to remove the waste gas of the pre-vacuum pump and to transmit it to the outside.
- Wear lint-free gloves when touching the inner parts of the specimen chamber or the speci-

Risk of injury: If a gas injection system (GIS) is used, irritant gases might be released from the precursors. Gases **Irritant gases** can cause irritation to eyes, skin, and respiratory system.

- Do not remove a reservoir from the gas injection system.
- Contact your ZEISS service representative to have an empty reservoir replaced.

- Never try to open a reservoir.
- For further information, refer to the GIS instruction manual.

risk: Disposal of aggressive or toxic chemicals

**Environmental** When disposing of aggressive or toxic chemicals, there is a threat of damage to the environment.

When disposing of waste that has been generated during a service operation (e.g. used rotary pump oil), comply with all national and local safety and environmental protection regulations.

#### 2.3.4 Electrical Hazards

Danger to life: Hazardous voltage inside the microscope

High voltages are present inside the microscope. Contact may cause burn or electrical shock.

- Ensure proper grounding. For more information, refer to the Installation Requirements docu-
- Only authorized ZEISS service representatives are allowed to service the microscope.
- Do not try to service the microscope yourself.

High leakage currents

Danger to life: High leakage currents are present in the microscope. Contact may cause burn or electrical shock.

- Ensure proper grounding. For more information, refer to the Installation Requirements document.
- Do not operate the microscope without the separate ground connection.

#### 2.3.5 High Pressure Hazards

property damage: High pressure in gas cylinders

Risk of injury or Gas cylinders containing for example nitrogen or compressed air have a high internal pressure of approximately 200 bar. If not properly handled, the contained gas can abruptly escape and cause the gas cylinder to move in an uncontrollable manner.

- Observe all safety labels on the gas cylinders and all safety instructions given by the gas cylinder manufacturer.
- Always operate gas cylinders in an upright position and secure them so they will not tip over.
- Before transporting gas cylinders, place protective caps on them.

#### 2.3.6 Magnetic Field Hazards

Risk of injury: Malfunction of medical devices near ion getter pumps

Magnetic fields present at the ion getter pumps may disturb the function of medical devices. The magnetic fields are also present if the microscope is switched off.

If you wear medical implants that are susceptible to magnetic fields (e.g. cardiac pacemakers), do the following:

- Keep a distance of at least 1 m from the ion getter pumps.
- Follow the safety instructions provided by the pump manufacturer.

#### 2.3.7 Mechanical Hazards

Risk of injury: Moving the specimen stage Fingers can be trapped by the moving specimen stage.

- Always close the chamber door before moving the specimen stage.
- To remove parts fallen into or near to the stage use a tool (e.g. tweezers) instead of your fingers.

Risk of injury: Closing the chamber door

Fingers can be pinched when closing the chamber door.

- Use the recessed grip or door handle to close the chamber door.
- Ensure not to get your fingers caught in the chamber door gap.

working distance

Risk of property When opening the chamber door, the microscope or specimen can be damaged if the specimen damage: Short stage is at a short working distance. If a BSD detector is inserted, it can be damaged as well.

> Always move the specimen stage to a long working distance before opening the chamber door

#### 2.3.8 Radiation Hazards

Danger to life: X- X-rays are generated inside the microscope during operation. This is unavoidable because elecrays trons are accelerated by voltages up to 30 kV.

- Do not remove any parts around the column and chamber that are essential for radiation protection.
- Use genuine ZEISS parts exclusively.
- Ensure that all local safety and X-ray protection regulations are met.
- Only authorized ZEISS service representatives are allowed to service the microscope.

The microscope is equipped with several radiation protection devices, which, under regular operating conditions, ensure that the microscope operates in accordance with the German X-ray protection regulation (RöV), the German radiation protection regulation (StrSchV) as well as with the EC Directive 2013/59/EURATOM.

In the EU, the operation of the microscope is permission-free as the following requirements are fulfilled:

- The acceleration voltage is limited to 30 kV.
- The local dose rate at a distance of 0.1 m from the accessible surface of the microscope does not exceed 1 μSv/h.
- A respective label is attached to the microscope.

Outside the EU, the user of the microscope has to comply with the local regulations of the country where the microscope is operated.

#### **Radiation Protection**

For questions regarding radiation protection, contact the ZEISS Radiation Safety Officer, Carl Zeiss AG, 73447 Oberkochen, Germany

phone: +49 (0) 7364 20 0

#### 2.3.9 Suffocation Hazards

Lack of oxygen

Danger to life: Gaseous dry nitrogen is used to vent the specimen chamber during specimen exchange and parts exchange. Inhaling nitrogen may cause unconsciousness.

- During specimen exchange, keep the chamber door open as short as possible.
- Do not inhale the air from within the specimen chamber.
- Ensure that the area around the microscope is sufficiently ventilated.
- If you begin to experience symptoms of asphyxia (for example: rapid breathing, loss of mental alertness and/or muscular coordination, depression of sensations, emotional instability, fatique) leave the room immediately and inform the facility's safety officer.

Concerning the hazards of nitrogen installations and associated safety precautions refer to the current version of the quideline IGC Doc 44/18: Hazards of Oxygen-Deficient Atmospheres, published by EIGA (European Industrial Gases Association).

To download the document:

- 1. Go to EIGA homepage www.eiga.eu.
- Select Publications > EIGA Documents.
- 3. From the list, select Doc. 44/18.
- 4. Click Download.

# 2.4 Safety Equipment

In order to prevent hazards to human health or property damage, the microscope is equipped with several safety features.

# 2.4.1 Protective Cover Panels

Due to hazardous voltages and X-rays inside the microscope, the microscope is equipped with protective cover panels.

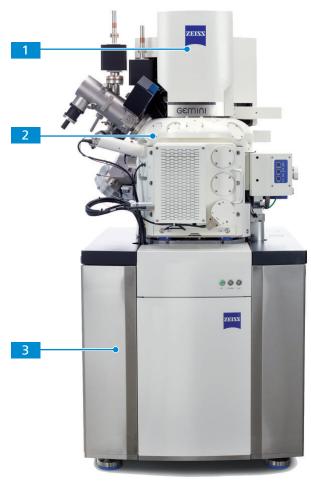


Fig. 1: Protective cover panels

- 1 Electron optical column protective cover panels
- 2 Specimen chamber protective cover panels
- 3 Plinth protective cover panels

Operation of the microscope is only allowed with attached protective cover panels.

#### 2.4.2 Main Switch

The Main Switch cuts off both phases of the mains power from the microscope.

The Main Switch guarantees an ampere interrupting capacity (AIC) of at least 10,000 A rms. In the OFF position, the Main Switch can be secured with a padlock against inadvertent activation, for example during repair and maintenance work.

The Main Switch is located at the rear side of the plinth.

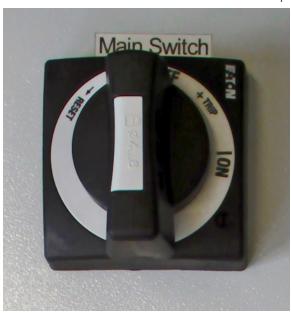


Fig. 2: Main Switch

# 2.4.3 Emergency Off (EMO) Option

With the Emergency Off (EMO) option, the microscope is equipped with the following additional safety equipment.

Microscopes with SEMI certification must be equipped with the Emergency Off (EMO) option.

## **Emergency Off (EMO) Button**

The EMO button is located on the plinth adjacent to the specimen chamber.

The EMO button must be pressed in an emergency to cut off mains power from the microscope and all devices connected to the AC Unit.

The EMO button must always be readily accessible and operable.

Up to three additional EMO buttons may be connected.



Fig. 3: EMO button

#### S2 (Start) Button

The green S2 (Start) button is attached below the MAIN switch at the rear side of the plinth.

The S2 (Start) button is required to confirm the setting of the MAIN switch. It cuts off all devices connected to the EMO box from the main power supply.

The S2 (Start) button must be pushed in the following cases:

- After the MAIN switch has been set to the ON position, or
- After the EMO button has been released.



Fig. 4: S2 (Start) button below the MAIN switch

#### 2.4.4 Locking Devices

The microscope is equipped with several locking devices.

## 2.4.4.1 Chamber Door Locking Device

The chamber door locking device ensures that the door of the specimen chamber is closed properly.

It is located at the inner bottom front side of the specimen chamber.

When this locking device is activated (i.e. no electrical contact) EHT Vac ready = no is indicated in the SmartSEM user interface. EHT and SE detector voltages are blocked.

# 2.4.4.2 Vacuum Locking Device

The vacuum locking device ensures that gun vacuum and system vacuum are better than the required thresholds.

# 2.4.4.3 Interlock System of Optional Airlock

The interlock function ensures that the gate valve can only be operated if the chamber door and the airlock door are properly closed.



Fig. 5: Airlock Error LED

Additional blocking functions ensure that the specimen can only be transferred if the following conditions are fulfilled:

- The airlock rod is retracted.
- The specimen stage is in transfer position.
- The EHT (Extra high tension) is off.
- The column chamber valve is closed.

This is to prevent any risk of damaging the airlock rod or the gate valve.

# 2.4.5 Lockout/Tagout Equipment

The Lockout/Tagout (LOTO) equipment isolates the workstation from potential hazards associated with the unexpected release of hazardous energy.

Performing a Lockout/Tagout [ > 93] can be necessary during

- maintenance tasks
- service work
- unscheduled repairs

At the site of installation, the electrical power connection and the fluid connections must be equipped with energy isolating devices.

These energy isolating devices (main shut-off devices)

- must be easily accessible
- must be mounted near the microscope in such a way that the person actuating or inspecting an energy isolating device is not be exposed to serious risks
- must close off the connections to the corresponding media when needed
- must be lockable in their off position in order to prevent accidental re-activation

The customer is responsible for

- having a working knowledge of the LOTO specification
- purchasing, distributing, and installing appropriate LOTO equipment
- auditing and enforcing compliance with LOTO procedures to all authorized personnel
- providing instructions on how to operate the energy isolating devices properly

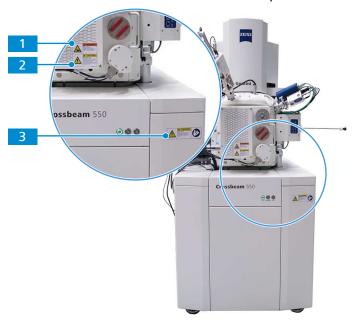
# **Required Energy Isolating Devices**

- Branch circuit molded case circuit breaker
- Main shut-off valves
  - Nitrogen supply
  - Compressed air supply
  - Cooling water supply

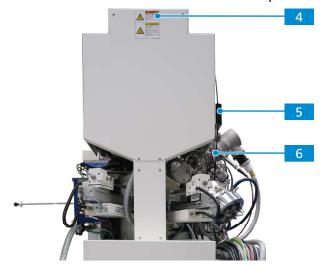
# 2.4.6 Safety Labels

Appropriate safety labels on the microscope warn operators of hazards. Each safety label is affixed close to the point where a particular hazard exists. Several labels also provide legal information.

Labels Attached to the Front Side of the Microscope



Labels Attached to the Rear Side of the Microscope



# Labels Attached to the Gun Head underneath the Cladding



Labels Attached to the Rear Side of the Plinth



**Labels Attached to the CEE Connector** 



The safety labels always need to be attached to the correct spots at the microscope. If a safety label is lost or unreadable, it needs to be reordered via the following reorder numbers:

# Position and Figure of the Safety La-

# Description

1

At the front of the chamber door.

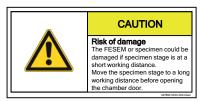


#### Risk of injury

Fingers could be trapped. Always close the chamber door before you move the stage.

Reorder no. 347800-0033-000-02en

2 At the front of the chamber door.



#### Risk of damage

The FESEM or specimen could be damaged if specimen stage is at a short working distance.

Move the specimen stage to a long working distance before opening the chamber door.

Reorder no. 347800-0033-000-04en

At the front of the plinth



#### **Avoid injury**

Make sure you have read and understood the instruction manual before operating this product.

Reorder no. 347800-0033-000-01en

4 At the rear of the electron optical column



# Hazardous voltage inside

Contact may cause burn or electric shock. Only authorized service Staff is allowed to service the equipment.

Disconnect power before opening.

Reorder no. 347800-0033-000-03en

At the ion getter pumps



#### Magnetic field

Can be harmful to pacemaker wearers.

Pacemaker wearers stay back 30cm (12 in.).

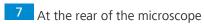
Reorder no. 360735-0000-034en

6 At the FIB column



#### Hazardous voltage symbol

Reorder no. 360400-0000-215



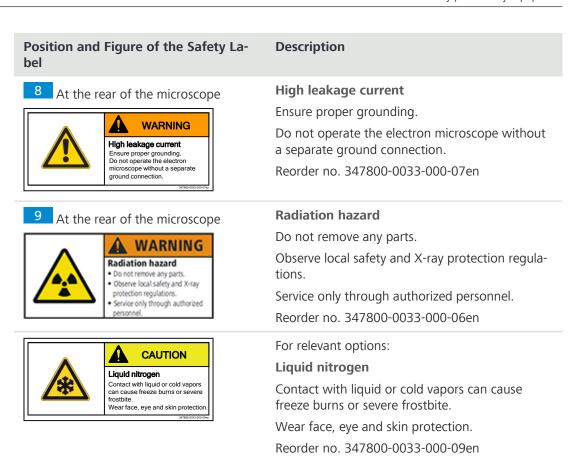


# **Suffocation hazard**

The specimen chamber is ventilated with gaseous nitrogen.

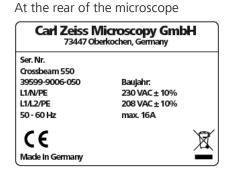
Ensure that the area around the electron microscope is sufficiently ventilated.

Reorder no. 347800-0033-000-08en



Underneath the cover panels of the microscope, there are some more safety labels, which are addressed to authorized ZEISS service representatives. These safety labels are described in the documents for ZEISS service representatives.





# Type plate

#### Position and Figure of the Legal In-Description formation At the rear of the microscope **Caution** X-rays are produced in this Scanning Electron Mi-**ACHTUNG:** croscope! In diesem Rasterelektronenmikroskop entstehen Röntgenstrahlen! Die Beschleunigungsspannung ist auf 30kV begrenzt. Örtliche Sicherheitsbestimmungen, The acceleration voltage is limited to 30 kV. Strahlenschutzverordnung und -gesetz einhalten. Observe local safety and X-ray protection regulations. **CAUTION:** Order no. 346000-0088-000 X-rays are produced in this Scanning Electron

Microscope! The acceleration voltage is limited to 30 kV. Observe local safety and X-ray protection regulations.

## **Position and Figure of the Type Plate**

11 At the rear of the microscope

#### Carl Zeiss Microscopy GmbH 73447 Oberkochen, Germany

Ser. Nr. Crossbeam 550 39599-9006-050

Baujahr: L1/N/PE 230 VAC ± 10% L1/L2/PE 208 VAC ± 10% 50 - 60 Hz max. 16A



#### Description

The Type plate contains a unique serial number, the Sigma model designation with the according part number, the manufacturing year, and the mains voltage for which the Sigma is configured.

Order no. 356100-9057-000 (Sigma 300)

Order no. 352100-9903-000 (Sigma 500)

# Position and Figure of the Type Plate

# **Description**

13 At the rear of the microscope

The Type plate contains a unique serial number, the EVO model designation with the according part number, the manufacturing year, and the mains voltage for which the EVO is configured, either 230 VAC or 120 VAC.

Order no. 354900-9040-000 (EVO10)

Order no. 354900-9041-000 (EVO15)

Order no. 354900-9042-000 (EVO25)

# 3 Product and Functional Description

# 3.1 System Overview

#### **Main Components**

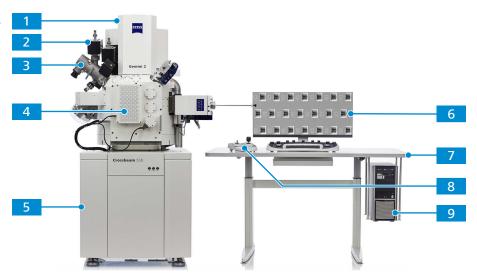


Fig. 6: Main components of the Microscope System

- 1 GEMINI II electron optical column

  Refer to Electron Optical Column | Gemini II [ > 31]
- 3 Ion-sculptor focused ion beam (FIB) column
  - Refer to Ion-sculptor Focused Ion Beam (FIB) Column (Optional) [ > 35]
- 5 Plinth with ON/STANDBY/OFF buttons
- 7 Work desk
- 9 Personal Computer (PC)

Specimen chamber with door handle

- 6 Monitor
- 8 Dual joystick
  - Refer to *Dual Joystick* [ 43]

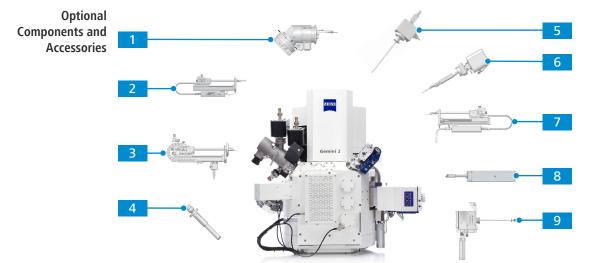


Fig. 7: Optional components and accessories

Multichannel Gas Injection System (GIS) for up to 5 precursor materials on a single flange

Refer to instruction manual Multi GIS

Annular STEM detector (aSTEM) for transmission imaging and quality control. Two different models are available (aSTEM4, aSTEM1). Detection of up to 4 channels in parallel is possible.

Local charge compensator for SEM imaging and analysis of non-conductive specimens

Refer to instruction manual Charge Compensator

5 Single needle GIS for high angle specimen access

Refer to instruction manual UniGIS

7 BSD detector for high efficiency BSE detection and angle selective material characterization. Four different models are available (aBSD4, aBSD1, BSD4, BSD1). Detection of up to 4 channels in parallel is possible.

Refer to BSD Detector [ 46] and aBSD Detector [ 47]

9 Airlock with optional navigation camera (80 mm or 200 mm wide) for fast and efficient specimen transfer and fast pumping times

> Refer to the respective instruction manual 80 mm Airlock or 200 mm Airlock

4 Electron flood gun for ion beam preparation of non-conductive specimens
Refer to instruction manual Flood Gun

Refer to aSTEM Detector [> 50]

6 Micro-manipulator for specimen modification and probing

8 EsB detector for finest z resolution without topographic artifacts and unique material contrast

Refer to *EsB Detector* [▶ 45]

## Further options:

Control panel

Refer to Control Panel [ 53]

Plasma Cleaner

Refer to instruction manual Plasma Cleaner

- Energy-dispersive X-ray spectrometer (EDS) for chemical analysis
- EBSD for crystallographic mapping
- SESI detector for Secondary Electron and Secondary Ion imaging Refer to SESI Detector [> 44]
- CL detector for the analysis of cathodoluminscent materials
   Refer to CL Detector [> 52]
- Nanopatterning and Visualization Engine (NPVE) for advanced patterning and lithography tasks

Information will be provided by the manufacturer

Electrostatic Beam Blanker for SEM

Refer to instruction manual Beam Blanker

Rapid Laser Ablation Upgrade
 Refer to instruction manual Rapid Laser Ablation Upgrade

Further options on request

# 3.2 Main Components

#### 3.2.1 Vacuum System

**Purpose** For operation of the microscope, the gun head, the column, and the specimen chamber have to be evacuated. The vacuum is essential to operate the gun and to prevent collisions of electrons with gas molecules.

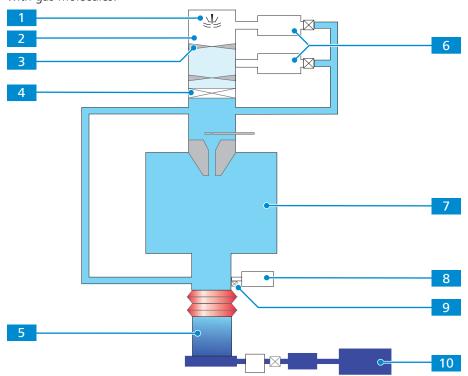


Fig. 8: Schematics of the vacuum system of a microscope with Gemini II column

- 1 Gun with filament
- 2 Gun head
- 3 Single hole aperture
- 4 Column chamber valve
- 5 Turbo pump
- 6 Ion getter pumps (IGP)
- 7 Specimen chamber
- 8 Penning gauge
- 9 Vent valve
- 10 Pre-vacuum pump

# Operating Principle

# System Vacuum

The pre-vacuum pump 10 and the turbo pump 5 evacuate the specimen chamber 7. The vacuum in the specimen chamber is measured by a Penning gauge 8. The detected vacuum values are displayed as System vacuum in the SmartSEM user interface. As long as the detected pressure in the specimen chamber is not ready for operation, the column chamber valve 4 is closed in order to separate the specimen chamber from the column.

#### **Gun Vacuum**

In the gun head, an ultra high vacuum is maintained by ion getter pumps  $\frac{6}{1}$ . The vacuum in the gun head is displayed as Gun vacuum in the SmartSEM software. It should be below  $1 \times 10^{-8}$  mbar.

#### Venting

The specimen is located in the evacuated specimen chamber. To open the specimen chamber for specimen exchange, you have to break the vacuum in a controlled manner. This is done by the Vent command via the SmartSEM user interface or by pressing the **Exchange** push button on the optional control panel.

When the Vent command is received, the column chamber valve closes and gaseous nitrogen flows into the specimen chamber via the vent valve 9. As soon as the pressure equilibrium is obtained, the chamber door can be opened to change the specimen.

#### **Evacuating**

In order to continue operation, the Pump command makes the pre-vacuum pump and the turbo pump evacuate the specimen chamber.

As soon as the vacuum in the specimen chamber is ready for operation, the column chamber valve opens and the EHT Vac ready message is displayed in the SmartSEM user interface. Gun and EHT can be switched on.

#### **Quiet Mode**

The automatically controlled **Quiet Mode** is optionally available. This option allows switching off the pre-vacuum pump after specimen exchange when the vacuum threshold is achieved.

# 3.2.2 Electron Optical Column | Gemini II

**Purpose** The GEMINI II column is the part of the microscope, where electrons are emitted, accelerated, deflected, focused, and scanned. Main characteristics of the GEMINI optics are the beam booster and an objective lens that consists of a combined electrostatic/electromagnetic lens doublet.

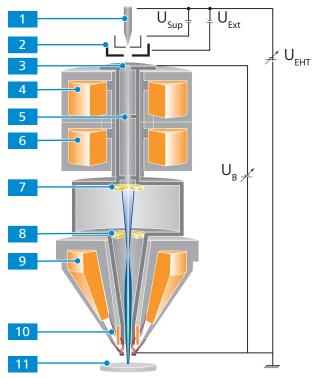


Fig. 9: Schematics of the electron optics

- 1 Gun
- 2 Extractor

Positive electrode that extracts electrons from the filament.

- 3 Anode aperture
- 4 Upper condenser
- 5 Single hole aperture
- 6 Lower condenser
- 7 EsB detector
- 8 InLens SE detector
- 9 Objective lens

Focuses the electron beam on to the specimen surface.

10 Scanning coils

Deflect the beam across the specimen surface in what is usually referred to as a raster scan.

- 11 Specimen
- U<sub>sun</sub> Suppressor voltage
- U<sub>Ext</sub> Extractor voltage
- U<sub>EHT</sub> Acceleration voltage
- U<sub>B</sub> Liner tube voltage

# Operating Gun **Principle**

A Schottky field emitter serves as gun 1. The filament is heated by applying the filament current. Electrons are emitted from the heated filament while an electrical field, called extractor voltage  $(U_{Ext})$ , is applied. To suppress unwanted thermionic emission from the shank of the Schottky field emitter, a suppressor voltage (U<sub>Sup</sub>) is applied as well.

#### **EHT**

The emitted electrons are accelerated by the acceleration voltage (U<sub>EHT</sub>). The beam booster (U<sub>B</sub>, booster voltage), which is always at a high potential if the acceleration voltage is 20 kV or less, is integrated directly after the anode. This guarantees that the energy of the electrons in the entire beam path is always much higher than the set acceleration voltage. This considerably reduces the sensitivity of the electron beam to magnetic stray fields and minimizes the beam broadening.

#### **Apertures**

The electron beam passes through the anode aperture 3 first, afterwards through a single hole aperture 5

The anode aperture defines the maximum possible probe current.

For the Gemini II column, two different column configurations are available:

40 nA high resolution configuration

Anode aperture diameter	Probe current	Typical application
55 μm*	10 pA to 40 nA	High resolution

100 nA high current configuration

Anode aperture diameter	Probe current	Typical application
90 μm*	10 pA to 100 nA	Combined high resolution and analytical investigations

#### Condenser

A double condenser system allows the continuous regulation of the probe current. The upper condenser 4 is used to continuously adjust the probe current. The lower condenser 6 is used for aperture matching of the objective lens in order to guarantee optimum resolution at each probe current and EHT setting.

#### Stigmator

The stigmator is located inside the condenser and compensates for astigmatism so that the electron beam becomes rotationally symmetrical.

## **Deflection System**

The electron beam is focused by the objective lens 9 onto the specimen 11 while being deflected in a point-by-point scan over the specimen surface by the scanning coils.

Before the electron beam exits the objective lens, the electrostatic lens creates an opposing field which reduces the potential of the electrons by +8 kV. The energy of the electrons reaching the specimen surface therefore corresponds to the set acceleration voltage (EHT).

#### **Signal Detection**

When the primary electron beam hits the specimen, certain interaction products are released, which can be recorded by specific detectors, e.g. the InLens SE detector 8. For more information see *Principle of Signal Detection* [▶ 37].

# 3.2.2.1 Beam Modes

With the GEMINI II column, different beam modes are available:

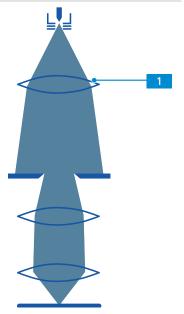
- High Resolution
- High Resolution Low Current
- Normal
- Minimum Probe Current
- Maximum Probe Current
- Fisheye
- Widefield

# **High Resolution**

# Characteristics Beam Path

The upper condenser has a low excitation which is varied in order to adjust the probe current in a limited range.

- Electron interaction effects are minimized
- High spatial resolution is guaranteed
- Probe current range is limited



# **High Resolution Low Current**

The characteristics and the beam paths of the High Resolution Low Current mode and High Resolution mode are the same, except the different operation of the gun.

Characteristics

#### Normal

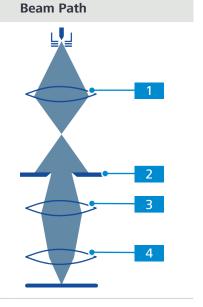
The upper condenser 1 focuses the beam and creates a crossover above the beam-limiting aperture 2. The upper condenser is adjusted to modify the probe current.

The lower condenser 3 is used for aperture matching of the objective lens 4 for optimum spatial resolution.

- Whole probe current range is accessible
- High spatial resolution is usually guaranteed

Instead of aperture matching it is also possible to adjust the amount of depth of field desirable. The lower condenser

- is then operated at increasing excitations.
- Provides a higher depth of field
- Useful to investigate specimens with a high aspect ratio or to navigate on a tilted specimen



#### **Minimum Probe Current**

The characteristics and the beam paths of Minimum Probe Current mode and Normal mode are the same, except the different operation of the gun.

#### **Maximum Probe Current**

The characteristics and the beam paths of Maximum Probe Current mode and Normal mode are the same, except the different operation of the gun.

# Fisheye

- Provides a huge field of view, allows you to image the whole specimen holder with the electron beam.
- Useful for an overview of large specimens and for specimen navigation.

#### Widefield

- Provides a huge field of view, allows you to image the whole specimen holder with the electron beam.
- Useful for an overview of large specimens and for specimen navigation.
- Can be used with EHTs between 100 V and 2000 V.
- Requires the SmartSEM software license Field Mode.

# 3.2.3 Ion-sculptor Focused Ion Beam (FIB) Column (Optional)

**Purpose** The Ion-sculptor Focused Ion Beam (FIB) column is the part of the microscope, where ions are emitted, accelerated, focused, and deflected.

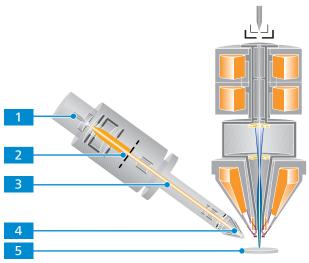


Fig. 10: Schematics of the ion optics

- 1 Ion source Liquid metal ion source of gallium (Ga+).
- 2 Variable apertures
- 3 Ion beam
- 4 Objective lens
- 5 Specimen

# Operating Principle

Gallium ions (Ga<sup>+</sup>) are extracted from a liquid metal ion source 1. The ions are accelerated by the acceleration voltage to an energy of maximum 30 keV. The ion emission is adjusted by the extractor and the suppressor voltage.

Gallium is used up during operation. Therefore, the gallium emitter cartridge is a consumable.

The gallium emitter has to be regenerated by heating from time to time; the heating procedure removes the gallium oxide, which has been created during operation.

#### Condenser

The electrostatic condenser collimates and focuses the ion beam.

#### **Probe Currents**

After passing the condenser, the beam current is defined by a set of software-controlled mechanical apertures. By using the different apertures in combination with the different condenser settings, the probe current can be continuously adjusted in the range between 1 pA and 100 nA.

## **Objective Lens**

The objective lens is designed as an electrostatic Einzel-lens system. It focuses the beam onto the specimen surface.

# 3.2.3.1 Imaging Modes

**Purpose** With the FIB option, different imaging modes are available to operate the microscope.

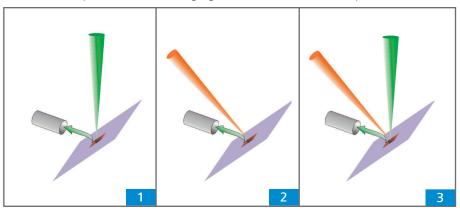


Fig. 11: Imaging modes available with the FIB option

Imaging Mode	FIB Mode	Characteristics	Typical Application
1 SEM imaging	SEM	<ul><li>Electron beam is active.</li><li>Ion beam is blanked.</li><li>The SE signal is synchronized to the SEM scan.</li></ul>	High resolution imaging.
2 FIB imaging	FIB	<ul><li>Electron beam is blanked.</li><li>Ion beam is active.</li></ul>	<ul><li>Channeling contrast imaging.</li><li>Voltage contrast imaging.</li></ul>
		<ul> <li>The SE signal is synchronized to the FIB scan.</li> </ul>	<ul><li>Defining milling patterns on the specimen surface.</li><li>Grain analysis.</li></ul>
3 Crossbeam operation	SEM + FIB	Image is composed of SEM and FIB components.	Setting the coincidence point.
	Mill	<ul><li>No image.</li><li>Mills with the milling parameters set (milling current).</li></ul>	<ul> <li>Ion beam milling or ion beam deposition.</li> </ul>
	Mill + SEM	Mills and generates a SEM image.	SEM real-time imaging of the ion beam milling or deposition.

#### 3.2.4 Detectors

# 3.2.4.1 Principle of Signal Detection

The interaction products most frequently used for the generation of images in scanning electron microscopy are secondary electrons (SEs) and backscattered electrons (BSEs).

# **Primary Electrons (PEs)**

Primary electrons are electrons forming the scanning beam before hitting the specimen.

# Secondary Electrons (SEs)

Secondary electrons are emitted from the topmost layer of the specimen.

SE1 Electrons

Electrons emitted at the point of impact between the beam and the specimen are known as SE1 type electrons. The amount of electrons emitted at the point of impact is related to the shape of the specimen.

Secondary electron detectors, such as the InLens SE detector, collect SE1 type electrons from the surface layer of the specimen and are thus ideal for displaying surface structures.

SE2 Electrons

The emergence of backscattered electrons from the specimen excites further emission of secondary electrons. These are known as SE2 type electrons.

Detectors that collect SE2 type electrons are especially suitable where the working distance is large. Surface detail as the effect of "lateral illumination" emphasizes the topography of the specimen.

### **Backscattered Electrons (BSEs)**

Backscattered electrons (BSEs) emerge from below the surface of the specimen (up to an order of  $\mu$ m). The number of electrons emitted at the point of impact is highly dependent on the mean atomic number of the specimen material. This means that a BSE image provides depth information and atomic number contrast.

BSE detectors are used to display the materials contrast because the backscatter coefficient is dependent on the mean atomic number of the material under investigation.

### **Transmitted Electrons**

This comprises primary electrons that are transmitted through an ultrathin specimen and weakly scattered primary electrons with a small range of angles. Depending on the material, primary electrons are scattered under different angles and can be detected by a STEM detector placed below the specimen. Unscattered electrons are detected in the center of the STEM detector and give a bright field image. Electrons scattered under higher angles are detected by outer areas of the STEM detector and produce dark field images.

# Cathodoluminescence (CL)

Electrons impacting on luminescent materials cause the emission of photons which may have wavelengths in the visible spectrum and can be imaged by specialized detectors.

# 3.2.4.2 Detectors Overview

The beam scans the specimen and initiates particles to be emitted. A detector collects the emission and produces an electric signal with an amplitude proportional to the number of particles at any given time.

Standard Detectors	Detected Signals	Typical Application
InLens SE Detector [▶ 39]	SE1	Surface structure
SE Detector [ > 40]	SE2	Topography
Optional Detectors	Detected Signals	Typical Application
SESI Detector [ • 44]	SE2 lons	Channeling contrast (crystal orientation)  Compositional contrast
EsB Detector [ > 45]	SE1 BSE	Surface structure Material contrast
BSD Detector [ > 46]	BSE	Compositional contrast
aBSD Detector [▶ 47]	BSE	Angular resolved BSE imag- ing Compositional contrast
aSTEM Detector [▶ 50]	Transmitted electrons	Diffraction contrast Compositional contrast
CL Detector [▶ 52]	Light photons	Mineralogy

#### 3.2.4.3 InLens SE Detector

Purpose The InLens SE detector is a high-efficiency detector for high resolution SE imaging and detects secondary electrons directly in the beam path. The detection efficiency of this detector results from its geometric position in the beam path and from the combination with the electrostatic/ electromagnetic lens.

**Position** The annular shaped in-column detector is located above the objective lens.

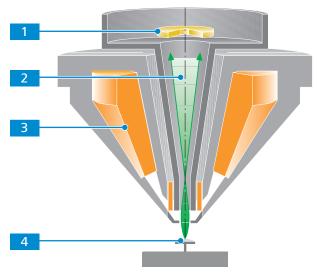


Fig. 12: Schematics of the InLens SE detector

- InLens SE detector
- Beam path
- Objective lens
- Specimen

**Operating** The primary electrons are accelerated by the acceleration voltage at the anode and, up to an ac-**Principle** celeration voltage of 20 kV, by an additional beam booster voltage of 8 kV at the liner tube. To ensure that the electrons reach the specimen surface 4 with the energy set as acceleration voltage, an opposing electrostatic field of the same magnitude as the beam booster voltage (8 kV) is generated at the end of the objective lens by the electrostatic lens. This electrostatic field acts as acceleration field for the SEs generated on the specimen surface.

> At the InLens SE detector, the electrons hit a scintillator. This generates a flash of light that is led out of the beam path and onto a photomultiplier by means of a lightquide. The photomultiplier converts the light information into an electronic signal, which can be displayed on the monitor.

The efficiency of the InLens SE detector is mainly determined by the electric field of the electrostatic lens, which decreases exponentially with the distance.

Thus, the working distance (WD) is one of the most important factors affecting the signal-to-noise ratio of the InLens SE detector.

As the tilt angle of the specimen surface affects the emission angle of the electrons, you should avoid strong specimen tilting.

# Info

The InLens SE detector can be used up to an acceleration voltage of 20 kV. At higher acceleration voltages, the beam booster and thus the field of the electrostatic lens are switched off. Without the field of the electrostatic lens, which attracts the secondary electrons, the efficiency of the InLens SE detector is reduced.

#### 3.2.4.4 SE Detector

Purpose The SE detector is an Everhart-Thornley type detector. It detects SEs as well as BSEs.

**Position** The SE detector is attached to the options ports plate.

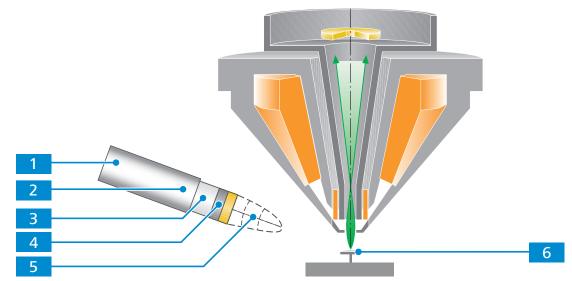


Fig. 13: Schematics of the SE detector

- 1 Preamplifier
- Photomultiplier
- Light guide
- Scintillator
- Collector grid
- Specimen

# Operating Principle

Electrons moving to the detector are attracted/repelled by the collector grid and directed to the scintillator. The electrons gain energy from the scintillator and thus are able to interact with a phosphor layer, which generates photons (light). The light travels up a light pipe to a photomultiplier. The photomultiplier multiplies the flashes of light and outputs a signal that can be used for imaging.

The collector voltage can be varied in the range between -250 V and +400 V.

A positive collector voltage generates an electrical field in front of the detector, thus directing the low energy SEs towards the scintillator.

# Info

For all standard applications, the collector bias should be set to +300 V.

### 3.2.4.5 Chamber CCD Camera

Purpose The microscope contains a CCD camera (charge-coupled device camera) inside the specimen chamber. It is referred to as the chamber CCD camera or chamberscope. It allows you to monitor the position of the specimen stage and particularly the distance between the objective lens and the specimen holder.

The chamber CCD camera is located at the backside of the specimen chamber. A second CCD camera can be installed on the left-hand side of the specimen chamber.

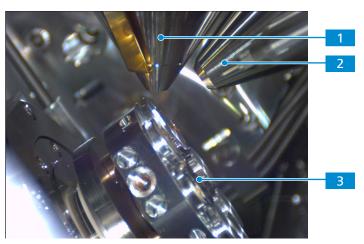


Fig. 14: Sample image from chamber CCD camera.

- 1 Objective lens of the SEM column
- 2 Objective lens of the FIB column
- 3 Specimen holder

## **NOTICE**

# Risk of property damage: Risk of collision

Use the chamber CCD camera to monitor the position of the specimen holder during stage movements. Pay particular attention to the distance between the objective lens and the top of the specimen. This applies to vertical movements, but also to horizontal movements, because a thick specimen may collide with the objective lens from the side.

The chamber CCD camera has two illumination modes. The chamber can be illuminated either with white light or with infrared light. Infrared light gives a grayscale image, whereas white light gives a color image. In standard settings the mode is automatically selected, depending on the imaging mode and the selected detectors. White light limits the performance of most detectors. Therefore infrared illumination is a fallback if white light cannot be used. The performance of diode detectors is negatively affected by infrared light. If a diode detector is selected, then by default the chamber CCD camera is disabled. The automatic selection of the illumination mode can be manually overwritten by the user.

The image of the chamber CCD camera can be adjusted by the user:

- Brightness, contrast, and CCD illumination can be optimized to improve the image.
- Certain display details can be chosen by zooming in and shifting. This can be achieved by turning the Magnification and Shift X or Shift Y knobs on the control panel, respectively.

# Info

It is highly recommended that the CCD illumination control is set to **Auto Detect**. This avoids any problems by the user forgetting to switch the illumination back for a different detector.

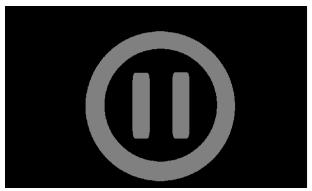


Fig. 15: Chamber CCD camera disabled as indicated by a pause sign (e.g. if a diode detector is selected).

# 3.2.5 Specimen Stage

**Purpose** The motorized eucentric specimen stage is used to navigate the specimen inside the specimen chamber.

Position The specimen stage is mounted on the chamber door. If the chamber door is closed, the specimen stage is inside of the specimen chamber.

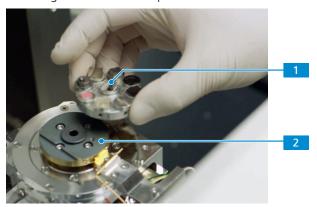


Fig. 16: Specimen stage with dovetail fitting for precise fitting

- Specimen holder
- Specimen stage

**Operating** When moving a tilted stage in X/Y direction, no displacement (moving out of focus) occurs. When **Principle** a pre-tilted specimen holder is used, X/Y movements require an adjustment of the Z position to stay in focus.

The stage can be operated using the *Dual Joystick* [ > 43] or using the SmartSEM software.

Axis	Description	Movement
X	X-axis	Movement towards or away from the chamber door (horizontal movement in the image)
Υ	Y-axis	Movement
Z	Height	Vertical movement (movement towards or away from the focal plane of the image)
М	Height	Movement of the specimen surface into the tilt axis at various working distances
R	Rotation	Stage rotation parallel to the X-Y plane
Т	Tilt	Stage tilt about an axis parallel to the X axis

The stage is eucentric, which means that the tilt axis intersects the beam axis. The specimen surface is located in the eucentric point, where the tilt axis meets the beam axis. This guarantees that the focus and the point of interest are maintained when the specimen is tilted at a certain working distance.

# 3.2.6 Dual Joystick

**Purpose** The dual joystick is used for stage control and specimen navigation.

**Position** The dual joystick is placed on the microscope desk.



Fig. 17: Dual joystick

- 1 T/Z joystick Controls the Z axis and the stage tilt (T).
- 2 Break push button Stops the stage in an emergency.
- 3 M push buttons Controls a second Z-axis (M) on super-eucentric stages to set the eucentric point of the specimen tilt on these stages.
- 4 X/Y/R joystick Controls the X- and Y-axes and the stage rotation by turning.

All axes are deflection-compensated. When the joystick is moved only slightly, the respective axis Principle moves slowly. Larger movements of the joystick result in a faster movement of the stage.

The X-, Y-, and Z-axes are magnification-compensated. When working at a low magnification, the stage moves relatively fast. At higher magnifications the stage movement is slower. The stage is moving with its maximum speed when viewing the specimen with the CCD (Charge Coupled Device) camera.

The different axes can also be moved simultaneously.

# 3.3 Optional Components and Accessories

# 3.3.1 Optional Detectors

# 3.3.1.1 SESI Detector

**Purpose** The Secondary Electrons Secondary Ions (SESI) detector is suitable to detect secondary electrons as well as secondary ions. In Crossbeam systems, the optional SESI detector replaces the SE detector

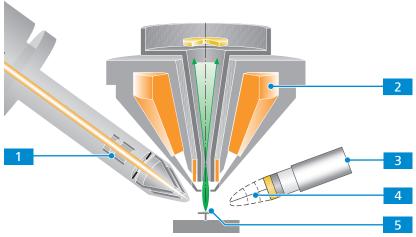


Fig. 18: Schematics of the SESI detector

- 1 FIB column
- 2 Objective lens
- 3 SESI detector
- 4 Collector grid
- 5 Specimen

# Operating Principle

Depending on the polarity of the collector voltage, either electrons or ions scattered from the specimen 5 are attracted by a collector grid 4 and accelerated to the converter. In the converter, both electrons and ions are converted into secondary electrons which are used to generate an image.

Detector Mode	FIB Mode	<b>Detected Signals</b>	Typical Application
SE mode typical collector voltage +300 V	SEM, FIB	Secondary electrons	Topography
lon mode typical collector voltage –4 kV	FIB	Secondary ions	Crystal orientation contrast, material contrast e.g. imaging of corrosion/oxidation caused by FIB processes in metals

#### 3.3.1.2 EsB Detector

**Purpose** The Energy-selective Backscattered (EsB) detector enables both SE and BSE detection. It can be used for high contrast topography or for compositional contrast examinations.

The SEs and BSEs generated at the impact point of the primary electron beam are intercepted by the low electrical field of the column. These electrons are accelerated by the field of the electrostatic lens.

Position The annular shaped in-column detector is located above the InLens SE detector.

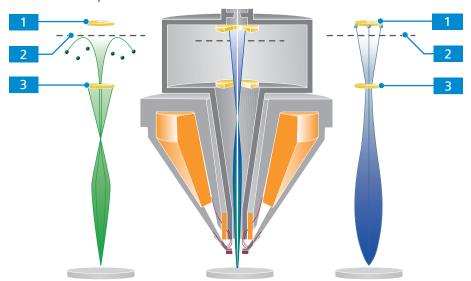


Fig. 19: Schematics. SE detection via InLens SE detector (left) and BSE detection via EsB detector (right)

- 1 EsB detector
- 2 Filtering grid
- 3 InLens SE detector

# Operating Principle

A small amount of SEs pass through the hole of the InLens SE detector 3 and would be observed by the EsB detector 1. To prevent detection of these SEs, a filtering grid 2 is installed in front of the EsB detector. By switching on the filtering grid voltage, the SEs are rejected and only BSEs are detected.

Below a landing energy of 1.5 kV, the filtering grid 2 has the additional function of selecting the desired energy of the BSEs. The operator can select the threshold energy of inelastically scattered BSEs to enhance contrast and resolution.

The combination of InLens SE detector and EsB detector all allows simultaneous imaging and mixing of a high contrast topography (SE) and a compositional contrast (BSE).

#### 3.3.1.3 BSD Detector

**Purpose** The BSD detector is a pneumatically retractable backscattered electron detector. It is used for high efficiency material characterization even at low-kV applications. It has four separate diode quadrants S1 to S4 and an additional shadow segment S5 for strong topography contrast.



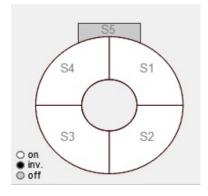


Fig. 20: BSD detector with four diode quadrants and a fifth shadow segment

# **NOTICE**

# Risk of property damage: Motorized specimen stage

Risk of damaging the detector when operating the motorized specimen stage.

• Retract the detector head completely after you have finished the work with the detector.

# Info

Risk of malfunction: The diode segments are sensitive to the light that is used for illumination in TV mode (infrared and white).

When you use a diode detector, always make sure that the TV illumination is switched off. If the CCD Mode is set to Auto Detect, then the TV illumination is automatically switched off when a diode detector is used.

The BSD detector has applications mainly in materials analysis and in the life sciences.

## Material analysis:

- Metallurgical sections
- Geological sections
- Complex materials
- Printed circuit boards
- Semiconductors
- Bond pads

# Life sciences:

- Mineral deposits in plant structures
- Bone structures

The BSD detector is available either with one video output channel (BSD1) or with four video output channels (BSD4). With BSD4 you can collect four channels in parallel, which can be displayed in Quad mode. Each channel can have an arbitrary combination of segments. This way, you can collect compositional images, topographical images, and custom combinations all at once.

Four channels are especially useful in combination with the program 3DSM, which provides a topographical reconstruction of the specimen. The program 3DSM acquires four images of the specimen and acquires each of these images with a different quadrant of the detector. This results in four images from four different directions. With the BSD4 detector you can acquire these four images all at once. An algorithm then calculates the topographic surface.

The BSD detector has a relatively large central hole and therefore has the advantage that it does not limit the field of view of the SEM and does not influence the electron optical properties of the objective lens. A disadvantage is that especially at low kV a lot of backscattered electrons are lost in the central hole and cannot be detected. A solution for that is the aBSD detector.

# Operating Principle

On the surface of the specimen, some of the primary electrons are backscattered. The backscattered electrons then move towards the silicon segments of the BSD detector. If the energy of the backscattered electrons is high enough, then the electrons pass through the very thin dead layer of the diode and create electron-hole pairs in the silicon segments.

In each individual segment, the charge separation due to the electron-hole pairs is measured as a current, which is used as a signal for image generation. Only electrons that have a high enough energy can create electron-hole pairs and can contribute to image generation. Electrons that have a lower energy (e.g. secondary electrons) are not detected by the BSD detector.

The emission of backscattered electrons from a specimen is related to the atomic number of the involved material: Elements with high atomic numbers generate more backscattered electrons (i.e. the backscatter coefficient is higher). When imaging, regions that contain elements with higher atomic numbers appear brighter. Regions that contain elements with lower atomic numbers appear darker.

Since the detector has a limited speed, it is recommended to use scan speed 6 or higher (slower), especially at small magnifications. The lower the gain is, the faster is the detector.

#### 3.3.1.4 aBSD Detector

Purpose The aBSD detector is a pneumatically retractable annular backscattered electron detector. It is used for high efficiency and angle selective material characterization even at low-kV applications. It has six separate diode segments, two inner concentric rings and four outer quadrants. The inner segments provide mostly material contrast whereas the four outer quadrants provide more topographical contrast.

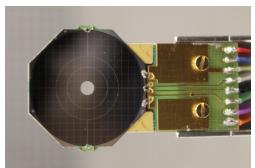




Fig. 21: The aBSD detector with two inner concentric segments and four outer quadrants

# **NOTICE**

# Risk of property damage: Motorized specimen stage

Risk of damaging the detector when operating the motorized specimen stage.

Retract the detector head completely after you have finished the work with the detector.

# Info

Risk of malfunction: The diode segments are sensitive to the light that is used for illumination in TV mode (infrared and white).

When you use a diode detector, always make sure that the TV illumination is switched off. If the CCD Mode is set to Auto Detect, then the TV illumination is automatically switched off when a diode detector is used.

The BSD detector has applications mainly in materials analysis and in the life sciences.

# Material analysis:

- Metallurgical sections
- Geological sections
- Complex materials
- Printed circuit boards
- Semiconductors
- Bond pads

## Life sciences:

- Mineral deposits in plant structures
- Bone structures

The BSD detector is available either with one video output channel (BSD1) or with four video output channels (BSD4). With BSD4 you can collect four channels in parallel, which can be displayed in Quad mode. Each channel can have an arbitrary combination of segments. This way, you can collect compositional images, topographical images, and custom combinations all at once.

Four channels are especially useful in combination with the program 3DSM, which provides a topographical reconstruction of the specimen. The program 3DSM acquires four images of the specimen and acquires each of these images with a different quadrant of the detector. This results in four images from four different directions. With the BSD4 detector you can acquire these four images all at once. An algorithm then calculates the topographic surface.

The BSD detector has a relatively large central hole and therefore has the advantage that it does not limit the field of view of the SEM and does not influence the electron optical properties of the objective lens. A disadvantage is that especially at low kV a lot of backscattered electrons are lost in the central hole and cannot be detected. A solution for that is the aBSD detector.

# Operating Principle

On the surface of the specimen, some of the primary electrons are backscattered. The backscattered electrons then move towards the silicon segments of the BSD detector. If the energy of the backscattered electrons is high enough, then the electrons pass through the very thin dead layer of the diode and create electron-hole pairs in the silicon segments.

In each individual segment, the charge separation due to the electron-hole pairs is measured as a current, which is used as a signal for image generation. Only electrons that have a high enough energy can create electron-hole pairs and can contribute to image generation. Electrons that have a lower energy (e.g. secondary electrons) are not detected by the BSD detector.

The emission of backscattered electrons from a specimen is related to the atomic number of the involved material: Elements with high atomic numbers generate more backscattered electrons (i.e. the backscatter coefficient is higher). When imaging, regions that contain elements with higher atomic numbers appear brighter. Regions that contain elements with lower atomic numbers appear darker.

Since the detector has a limited speed, it is recommended to use scan speed 6 or higher (slower), especially at small magnifications. The lower the gain is, the faster is the detector.

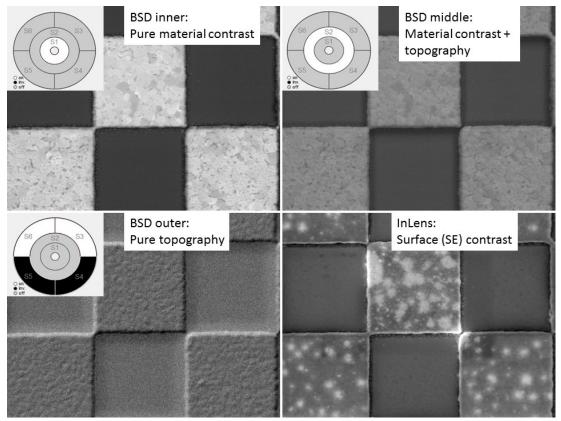


Fig. 22: Quad mode showing different contrast on different segments of the aBSD detector: Segment S1: Pure material contrast (top left), Segment S2: Material contrast and topography (top right), Segments S3 to S6: Pure topography (bottom left). For comparison: Surface contrast seen with the InLens SE detector (bottom right)

At small magnifications, the field of view is limited by the hole inside the aBSD detector:

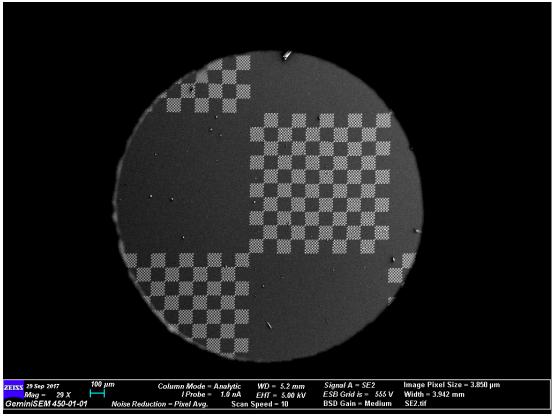


Fig. 23: Central hole of the aBSD detector

The central hole is laser cut. As a result of this process, there is some silicon that beads up in areas near the hole, but this silicon is conducting. It is therefore not charging up and not disturbing your image quality.

# **NOTICE**

# Risk of property damage: Short working distance

When inserted, the aBSD detector is positioned directly underneath the objective lens. The lower edge of the detector is then located at a working distance of 1.5 mm. If you move the specimen to a working distance below 1.5 mm, then you damage the aBSD detector.

- ▶ Do not move the specimen to working distances below 2 mm.
- ▶ Be careful when you tilt the specimen.

#### 3.3.1.5 aSTEM Detector

**Purpose** The optional aSTEM (annular Scanning Transmission Electron Microscopy) detector consists of an electron detector underneath an ultrathin specimen.

The aSTEM unit is equipped with diodes that are switched on or off in order to allow dark field and bright field imaging.

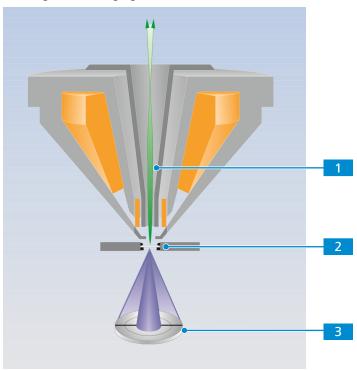


Fig. 24: aSTEM detector

- 1 Incident electron beam (primary electrons)
- 2 Thin specimen
- 3 aSTEM detector

# Info

Risk of malfunction: The diode segments are sensitive to the light that is used for illumination in TV mode (infrared and white).

When you use a diode detector, always make sure that the TV illumination is switched off. If the CCD Mode is set to Auto Detect, then the TV illumination is automatically switched off when a diode detector is used.

**Operating** The aSTEM detector is a pneumatically retractable multi-mode detector with a 12-stub specimen **Principle** holder for bright-field and dark-field detection.

The diodes of the aSTEM detector collect transmitted electrons below the ultrathin specimen.

A special arrangement of the diodes allows a parallel detection of bright field (BF), oriented dark field (ODF), annular dark field (ADF), and high angle annular dark field (HAADF). There are one bright field segment (S1), two dark field segments (S2 and S3), one annular dark field segment (S4), and one high angle annular dark field segment (S5).

Two different models are available:

- The aSTEM4 allows detection of four channels in parallel.
- The aSTEM1 only collects one signal at a time.

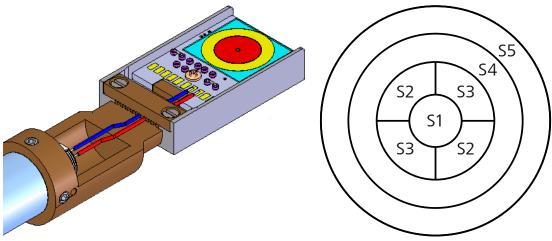


Fig. 25: The aSTEM detector head and the arrangement of its diodes

# **Operating Modes**

The most commonly used STEM modes are predefined and can be selected from the drop-down menu in the STEM Control panel.

The diagram in the STEM Control panel displays details concerning the diode status and the diode arrangement.

Each diode segment can have the following status:

- On: The signal is added to the total signal
- Inverted (Inv.): The signal is inverted and then added to the total signal
- Off: The signal is not used

# **NOTICE**

# Risk of property damage: Motorized specimen stage

Risk of damaging the detector when operating the motorized specimen stage.

▶ Retract the detector head completely after you have finished the work with the detector.

#### 3.3.1.6 CL Detector

Purpose The Cathodoluminescence (CL) detector is an inclined detector that allows efficient visible or ultraviolet light collection. The CL detector is ideal for use in geology, mineralogy, and materials science applications where it can help in internal structural examination of rocks, ceramics, and semiconductors.

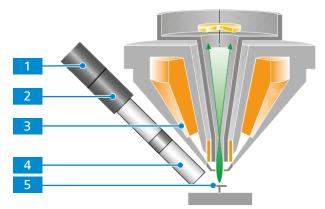


Fig. 26: Schematics of the CL detector

- Preamplifier
- Photomultiplier
- Objective lens
- Light guide with collector electrode
- Specimen

# Principle

Operating The prerequisite for using this detector is that the specimen emits light when interacting with the primary electron beam. Differences in crystal structure or the presence of impurities in a cathodoluminescent material result in variations in the energy gap between the filled valence bands and the empty conduction bands, and consequently a change in the CL emission.

> The light (photons) emitted by the specimen is collected by the CL detector and converted into a signal for imaging.

The CL detector is fully integrated into the automatic brightness and contrast control of the microscope and can be used simultaneously with any of the detectors without degrading their performance.

The detector can be used during energy-dispersive X-ray spectrometer (EDS) measurements and wavelength-dispersive spectrometer (WDS) measurements at any valid magnification.

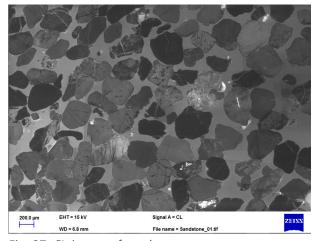


Fig. 27: CL image of sandstone

#### 3.3.2 Control Panel

**Purpose** The control panel allows direct access to 14 of the most frequently used functions. It integrates a full sized keyboard, 11 turning knobs, and 8 push buttons.

**Position** The control panel is placed on the work desk.



Fig. 28: Control panel

- 1 Stigmator X | Stigmator Y Shapes the beam roundness by changing the stigmation deflectors.
- 2 Aperture X | Aperture Y
  Adjusts the mid column shift and tilt deflectors for aligning the beam along the column axis.
- 3 Scan Rotate

Rotates the scanning pattern 360° continuously.

This turning knob has a push button function to deactivate the scan rotate function and reset the scan rotation to 0°.

4 Shift X | Shift Y

Shifts the scanned region of the specimen in the X and Y directions.

- 5 Brightness | Contrast
  - Brightness

Adjusts the image acquisition chain offset for the currently selected detector. Each configured detector stores its own brightness.

Contrast

Adjusts the gain of the currently selected detector.

- 6 Magnification | Reduced
  - Magnification

Adjusts the magnification of the system.

Reduced

Changes the scan field to a reduced area. The size of the area is determined by the current sub scan area settings.

7 Wobble

Sweeps the acceleration voltage. If the aperture is slightly misaligned, a shift in X and/or Y direction can be observed.

8 Freeze

Stops the scan and grabs one complete frame at the current imaging conditions.

- 9 Exchange | Resume
  - Exchange

Starts the pre-defined macro for specimen exchange with the airlock.

Resume

Starts the pre-defined macro to finish specimen exchange with the airlock.

10 Camera

Switches to chamber view.

- 11 Focus | Scan Speed +/-
  - Focus

Changes the focal point of the column by adjusting the magnitude of the objective lens.

Scan Speed +/-

Increases (+) or decreases (–) the scan speed by doubling or halving the beam dwell time with each click step.

# **4 Software Description**

# 4.1 SmartSEM

#### 4.1.1 SmartSEM User Interface

The SmartSEM software graphical user interface (GUI) allows you to monitor and operate most of the active components of the microscope.

The following screenshot indicates the main elements of the SmartSEM user interface:

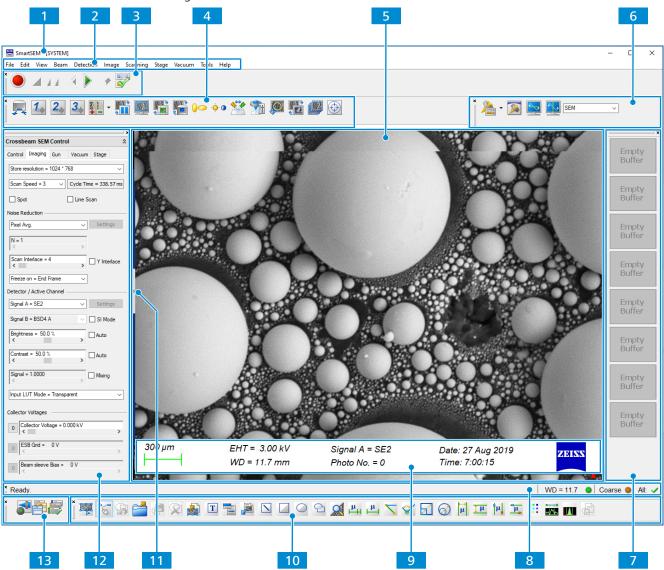


Fig. 29: Screen layout of the user interface

- 1 Title Bar
  - Displays the name of the user interface and the logged-on user.
- 3 AVI Toolbar
  - Contains the controls to set up, record, and playback video sequences of scanned images.
- 5 Image Area with Data Zone
  Displays image information and acquisition parameters from the microscope.

- 2 Menu Bar
  - Enables you to access to SmartSEM features via sub-menus.
- 4 Toolbar
  - Provides quick access to SmartSEM tools.
- 6 FIB Toolbar

  Contains the controls to configure the FIB column.

7 Thumbnails Panel

Displays thumbnail views of the contents of the eight image buffers.

9 Data Zone

Displays image information and acquisition parameters from the microscope.

11 Panel Configuration Bar

Enables you to choose the panels to be placed in the Docking Panel.

13 Mini Bar

Provides quick access to recently used dialogs and to the recipe management.

8 Status Bar

Displays the current machine state and contains the SEM Control Buttons.

10 Annotation Bar

Enables you to add information to the SEM image and provides several measurement functions.

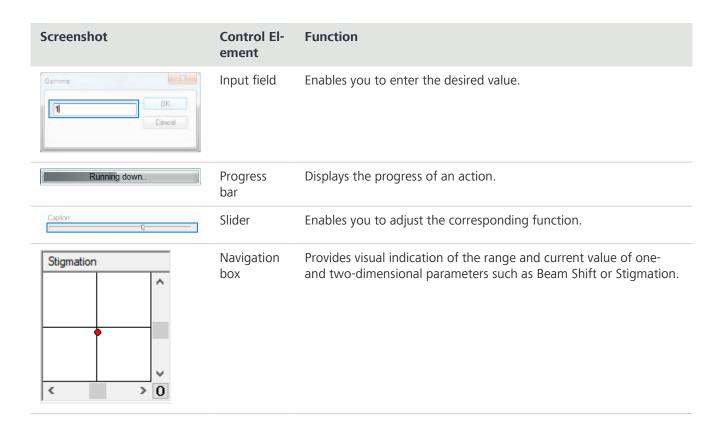
12 Docking Panel

Enables you to arrange frequently used SmartSEM panels for convenient access.

# 4.1.2 Graphical Control Elements

The following graphical control elements are used in the SmartSEM GUI.

Screenshot	Control El- ement	Function
Gun Apertures Stage  Detectors Scanning Vacuum  System Vacuum = 4.00e-004 Pa  Gun Vacuum = 2.22e-007 Pa  Vent inhibit = Beam Present  Vac Status = Ready	Tab	Provides a group of graphical control elements.
SEM Conversion  SEM Crist  Reference Image  Display Rectangle  Hide Rectangle  Create Reference	Section	Forms a group of control elements with related functions.
Pump	Button	Enables you to start an action.
Signal B = AsB # W Mixing	Checkbox	Enables you to activate or deactivate a function.
Signal A = InLens  AsB ESB HE-SE2 InLens TV STEM InlensDuo AsB4 Ch1  Input LUT AsB4 Ch1	Drop-down list	Enables you to select the desired element.
Signal Adjust Input LUT  Auto 8C = Off   Trans	Radio but- ton	Enables you to activate the desired option.
Gamma = 1.0000	Scroll bar	Enables you to adjust a value by moving the scroll bar or pressing the arrow button until the desired value is set.
Vac Status = Ready	Readout	Displays the status of a system entity.
		Enables you to select an action or a value by opening a dialog with an input field.



# 4.1.3 User Access Levels and User Privileges

The user access level defines which parameters are displayed for selection purposes, e.g. in the status window or annotation parameter selection.

SmartSEM distinguishes different user access levels. Depending on the user access level, different parameters are accessible. User profiles are defined by the administrator.

Access: Menu Bar > Tools > Administrator

User Access Level	Description
Novice	Only the items assigned to the novice category are accessible. These include most frequently used parameters.
Expert	Items assigned to the novice and expert category are accessible.  These include parameters useful for advanced operators.
Service	All items are accessible, also including infrequently used items and calibrations.

Additional to the user access levels there are user privileges which are part of the user profile:

Checkbox	Privilege
Calibration	Enables the user to perform instrument calibration operations.
Change Image Directory	Enables the user to change the location where all images are saved.
Change Toolbar	Enables the user to change the toolbar.
Change User Directory	Enables the user to change the location where all user specific parameters and configurations are saved.
Extractor	Enables the user to change the extractor voltage.

Checkbox	Privilege		
FIB Probe Alignment	Enables the user to adjust the probe currents.		
Gun Align	Enables the user to modify the alignment of the electron beam.		
Gun Off	Enables the user to switch off the field emission filament.		
Mill Defaults	Enables the user to modify the default settings for FIB milling.		
Stage Initialise	Enables the user to initialize the motorized stage.		
Supervisor	<ul> <li>Enables the user to perform the following actions:</li> <li>Start the Administrator, create and edit users</li> <li>Set User Max EHT</li> <li>Modify the filament current</li> <li>Set up, edit, and delete global stage coordinates</li> <li>Save common macros and toolbars</li> <li>Save common recipes</li> <li>Activate Partial Vent on Standby, Z Move on vent, Protect Z, Go to HV@Shutdown, EHT Off &amp; Log Off and Leave Gun ON at Shutdown.</li> <li>Use the bakeout function</li> <li>Start the FIB filament heating.</li> </ul>		

# 4.1.4 SmartSEM Program Suite

The SmartSEM Program Suite comprises the EM server, which implements the internal communication between control software and microscope hardware, plus several programs and utilities.

The main purpose of the SmartSEM Program Suite is to access all necessary microscopy parameters and software features to capture SEM data and optimize image acquisition.

Access: Windows start menu > SmartSEM

Program	Description
ChamberScope	Enables you to display the chamberscope image and the detector image at the same time.
	Option, requires particular hardware.
FTP Image Archiving	Enables you to transfer data via FTP.
	License: REMARCH
ReadMe	Contains important information on the currently installed version.
Release Notes	Contains an overview of all SmartSEM versions including new developments and specific details.
RemCon32	Serial interface for remote operation via RS232, e.g. for EDX
	License: REMCON
Sample Holder Gallery	Enables you to inspect the dimensions of all possible specimen holders as well as to set the dimensions of the custom specimen holders.
	Enables you to activate the available specimen holders for SmartSEM.
SEM Drift Correction	Enables you to compensate for the drift of the specimen by using a reference image and by controlling the beam shift.
	License: DRIFT-CORR
Slideshow speed set- ting	Enables you to adjust the slideshow speed for the Windows Photo Viewer.
SmartSEM Adminis- trator	Enables you to manage user profiles and configure instruments.
SmartSEM User Accounting	Enables you to record important information during individual working sessions, e.g. logon/logoff time, number of TIFF files exported etc.
SmartSEM User Interface	Main software application

Access: Windows start menu > SmartSEM Service

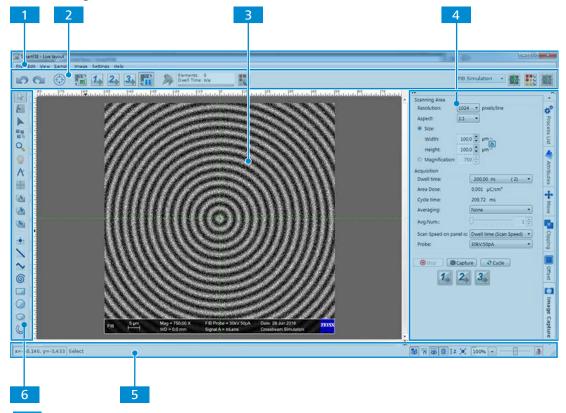
Program	Description
Calibration Wizard	Service activities, for ZEISS service representatives only
Gun Monitor	Enables you to monitor important parameters of the microscope.
GUN Service	Service activities, for ZEISS service representatives only
Piezo Configurator	Service activities, for ZEISS service representatives only
Service Centre	Provides an overview of the state of the microscope.
Smart Stage Map- ping	Service activities, for ZEISS service representatives only

Program	Description
SmartBackup Tool	Enables you to back up configuration and calibration data.
Stage Administrator	Service activities, for ZEISS service representatives only
Upgrade Scangen Firmware	Service activities, for ZEISS service representatives only
Upgrade Server Database	Service activities, for ZEISS service representatives only
Merlin Alignment Wizard	Service activities, for ZEISS service representatives only
Merlin Database Wizard	Service activities, for ZEISS service representatives only

#### 4.2 SmartFIB

#### 4.2.1 SmartFIB User Interface

The following screenshot indicates the main elements of the SmartFIB user interface:



## 1 Menu Bar

The menus on the Menu Bar contain basic commands that you need to work with Smart-FIB. The functionality depends on the selected mode.

# 2 Standard Toolbar

Contains various buttons for quickly accessing a subset of the commands contained in the Menu Bar.

Additionally, there are various exclusive functions, such as previews and mode switching.

### 3 Working Area

In the Working Area, the following items are displayed:

- Live Mode: captured image and patterning elements
   Editing of patterning elements is possible only in Live Mode.
- Sample Mode: Virtual Sample and writing positions
- EPD Mode: captured image and thickness map

# 4 Control Panel

Contains tabs for controlling the FIB process. The range of visible tabs depends on the selected mode.

# 5 Status Bar

- Left hand side: informs you about the current mouse position in the Working Area and indicates the selected tool, e.g. Vertex.
- Right hand side: enables you to control some exclusive properties of the Working Area.

5 Tools Toolbar

Contains tools for the Working Area. The range of visible tools depends on the selected mode.

# 4.2.2 Graphical Control Elements

The following graphical control elements are used in the SmartFIB GUI.

Screenshot	Control Element	Function
Gun Apertures Stage Detectors Scanning Vacuum  System Vacuum = 4.00e-004 Pa Gun Vacuum = 2.22e-007 Pa Vent inhibit = Beam Present Vac Status = Ready	Tab	Provides a group of graphical control elements.
Reference Image  Display Rectangle  Hide Rectangle  Create Reference	Section	Forms a group of control elements with related functions.
Pump Vent	Button	Enables you to start an action.
Signal B = AeB	Checkbox	Enables you to activate or deactivate a function.
Signal A = InLens  AsB ESB ESB HE-SE2 InLens TV STEM InlensDuo AsB4 Ch1  Input LUT AsB4 Ch1	Drop-down list	Enables you to select the desired element.
Signal Adjust Input LUT  Auto BC = Off   Trans	Radio button	Enables you to activate the desired option.
Gamma = 1.0000	Scroll bar	Enables you to adjust a value by moving the scroll bar or pressing the arrow button until the desired value is set.
Vac Status = Ready	Readout	<ul> <li>Displays the status of a system entity.</li> <li>Enables you to select an action or a value by opening a dialog with an input field.</li> </ul>
Gamma DK Cancel	Input field	Enables you to enter the desired value .
Caption C	Slider	Enables you to adjust the corresponding function.
Precision:  Delay:  Cycle delay:  not valid no	Expandable section	Enables you to expand or collapse the section as required.

# 4.2.3 SmartFIB Program Suite

The SmartFIB program suite comprises two main programs: SmartFIB and Designer (requires the license CREATOR). Each of these programs has a different field of use.

The main purpose of the SmartFIB program suite is to transfer geometric elements to a specimen with the help of a particle beam. This process is referred to as "exposure".

Access: Windows Start Menu > Programs > SmartSEM

Program	Description
SmartFIB	<ul> <li>Main tool for online/live work on the microscope</li> </ul>
	<ul> <li>Milling/etching/deposition of patterning elements</li> </ul>
	<ul> <li>Provides the following modes:         <ul> <li>Live Mode: Mainly used for editing patterns and structures and creating recipes</li> <li>Sample Mode: Mainly used for creating recurring/automated workflows</li> <li>EPD Mode: Used for thickness determination of a TEM lamella</li> </ul> </li> </ul>
Designer	<ul> <li>Offline creation of layouts: Arrangement of elements in the scanning area</li> </ul>
	<ul> <li>Interaction with Sample Mode: Used as a drawing tool for Sample Mode</li> </ul>

5 Installation ZEISS

# **5** Installation

Unpacking, installation, and first start-up are carried out by an authorized ZEISS service representative.

An excerpt of the installation requirements can be found under *Installation Requirements* [\* 114]. For more details refer to the document Installation Requirements.

# 6 Operation

# 6.1 Starting the System

# 6.1.1 Energizing the Microscope

# ⚠ WARNING

# Risk of injury: Restart after emergency off

If the reason for the emergency off is not eliminated, it may be dangerous to restart the microscope.

- If the microscope has been de-energized due to an emergency, ensure that the reason for the emergency off does not exist anymore.
- Make sure it is safe to energize the microscope.

- **Prerequisite** ✓ The microscope has been de-energized by turning the **MAIN** switch to the **OFF** position.
  - Alternatively, the microscope has been de-energized by pressing the Emergency Off (EMO) button.
  - 1. Verify that the main shut-off valves for compressed air, nitrogen, and cooling water at the facility installation are operable. Otherwise open and unlock the main shut-off valves.
  - 2. If the Emergency Off (EMO) option is installed, pull the EMO button to release it.
  - 3. Set the **MAIN** switch to the **ON** position.



4. If the Emergency Off (EMO) option is installed, press the green **S2** button to confirm the setting of the **MAIN** switch.



# 6.1.2 Starting the Microscope

- **Prerequisite** ✓ The microscope is energized.
  - 1. At the front of the plinth, press the **ON** button.
    - → The **ON** button blinks green while the system is activated.
    - → When all subsystems are fully activated, the **ON** button lights up green permanently.



## **6.1.3 Starting SmartSEM**

- 1. Power up the computer and log in.
- 2. Start the SmartSEM user interface via the ZEISS SmartSEM icon on the desktop. Alternatively, select Windows start menu > SmartSEM > SmartSEM User Interface.
  - → The EM Server opens while loading various drivers. The EM Server implements the internal communication between software and hardware of the microscope.
  - → The EM Server Log On dialog is displayed.
- 3. Enter the user name and password.
- 4. Click OK.
  - → The SmartSEM user interface opens and is ready to operate the microscope.

# 6.1.3.1 Calling up the Help

There are different ways to access topics in the Online Help.

Function	Menu	Shortcut	Control Elements
Startup page	Help	F1	_
Table of Contents	Help > Contents	Ctrl+F1	_
Context-sensitive	_	<ul><li>Shift+F1</li><li>F1 on focus</li></ul>	Question mark icon in the main window and in modal dialogs

Detailed information about using the help system is given in the Online Help directly.

# 6.1.3.2 Keyboard Shortcuts

The following keys are shortcut keys and have special meaning.

Shortcut	Function
<f2></f2>	Toggles Tool Bar on/off
<f2 +="" shift=""></f2>	Hysteresis removal
<f3></f3>	Closes all windows except the Tool Bar and Status Bar
<f3 +="" shift=""></f3>	Toggles PC Plane ON/OFF

Shortcut	Function	
<f4></f4>	Step to next Magnification Table entry, or Undo Centre Feature Magnification	
<f4 +="" ctrl=""></f4>	Step to previous Magnification table entry	
<f4 +="" shift=""></f4>	Exit from Magnification Table mode	
<f5>, <f5 +="" shift=""> <f6>, <f6 +="" shift=""> <f7>, <f7 +="" shift=""> <f8>, <f8 +="" shift=""></f8></f8></f7></f7></f6></f6></f5></f5>	User defined macros	
<f9></f9>	Keys help (displays this information)	
<f11>, <f11 +<br="">SHIFT&gt;</f11></f11>	User defined macros	
<f12>, <f12 +<br="">SHIFT&gt;</f12></f12>	Aborts Stage Movement	
<tab></tab>	Toggle coarse/fine	
<ctrl +="" tab=""></ctrl>	Performs Centre Point	
<ctrl +="" +<br="" shift="">TAB&gt;</ctrl>	Performs Centre Feature	
<home></home>	Resets Beam Shift to zero	
<scroll lock=""></scroll>	Toggles Freeze/Unfreeze	
<pause></pause>	Causes currently executing macro to continue	
<*>	Performs Find Image function	
<ctrl +="" 2=""></ctrl>	Loads Second Image Window from display	
<ctrl +="" a=""></ctrl>	Switches Annotation panel ON	
<ctrl +="" b=""></ctrl>	Display Toolbar View dialog	
<ctrl +="" d=""></ctrl>	Toggle Data Zone ON/OFF	
<ctrl +="" e=""></ctrl>	Calls the Export TIFF dialog	
<ctrl +="" f=""></ctrl>	Starts Auto Focus fine	
<ctrl +="" +<br="" shift="">F&gt;</ctrl>	Starts Auto Focus coarse	
<ctrl +="" g=""></ctrl>	Switches Crossbeam SEM Control Panel ON	
<ctrl +="" i=""></ctrl>	Switches SEM Status Panel ON	
<ctrl +="" m=""></ctrl>	Switches to Annotation and inserts Point to Point Marker	
<ctrl +="" alt="" m=""></ctrl>	Enable/Disable the Movable Crosshairs Marker	
<ctrl +="" alt="" f=""></ctrl>	Enable/Disable Mouse Following for Movable Crosshairs Marker	

Shortcut	Function
<ctrl +="" 0=""></ctrl>	Calls the Import TIFF dialog
<ctrl +="" p=""></ctrl>	Performs the Print Image function
<ctrl +="" s=""></ctrl>	Calls the Export TIFF dialog to save the image
<ctrl +="" alt="" s=""></ctrl>	Performs Auto Astigmatism Correction
<ctrl +="" +<br="" shift="">S&gt;</ctrl>	Performs Auto Astigmatism Correction with Auto Focus
<ctrl +="" t=""></ctrl>	Calls Text Annotation
<ctrl +="" v=""></ctrl>	Displays the Vacuum status information
Keypad <+>	Faster Scan
Keypad <->	Slower Scan
ARROW Keys	See Use of ARROW Keys
Image Buffer keys	See Image Buffer
<shift> and dou- ble click</shift>	Performs Centre Point function

# 6.2 Obtaining a First Image

# Info

Mobile phones in the microscope room can cause image quality infringements and in worst case workflow interruptions.

Purpose This section describes basic procedures to obtain an image using the SE detector. To simplify the procedure, the description uses the Crossbeam SEM Control panel and status bar functions in the SmartSEM software.

Overview The procedure contains the following steps:

- Preparing the Specimen Holder [▶ 69]
- Loading the Specimen Chamber [▶ 70]
- Locating the Specimen [▶ 72]
- *Switching on the Gun* [ > 73]
- *Switching on the EHT* [▶ 74]
- Acquiring an Image [▶74]
- Optimizing the Image [▶ 76]
- Saving the Image [▶ 78]

# 6.2.1 Preparing the Specimen Holder

# **Parts and Tools**

Designation	Part no.
Allen key, 1.5 mm	Delivered with the microscope
Stub	Delivered with the microscope
Tweezers for specimen	Delivered with the microscope
Specimen holder	Delivered with the microscope
If necessary: carbon tape, conductive carbon, adhesive metal tape, or similar	_
Appropriate specimen (with conducting properties, e.g. gold on carbon)	_
Lint-free gloves	_

# **NOTICE**

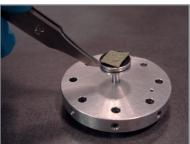
# Risk of property damage: Contamination caused by fingerprints

Contamination caused by fingerprints can lead to vacuum deterioration or prolonged pumping times.

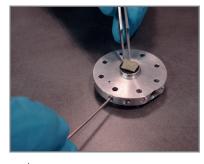
- Always wear lint-free gloves when touching the specimen, specimen holder, or stage.
- 1. To attach a specimen to the stub, use conductive carbon, adhesive metal tape, carbon tape, or similar.
  - Ensure that the specimen area that you want to analyze is in proper contact with the stub.



2. To insert the stub into the specimen holder, use tweezers.



3. To fix the stub to the specimen holder, tighten the location screw with the Allen key.



4. Note down which fix position is occupied by the specimen.

## 6.2.2 Loading the Specimen Chamber

#### Purpose

## Info

If your microscope is equipped with the optional airlock, use the airlock for loading the specimen chamber. For more information refer to the respective instruction manual.

# **Overview** The procedure contains the following steps:

- Displaying the Crossbeam SEM Control Panel [▶ 70]
- Driving the Stage to a Low Position [> 70]
- Venting the Specimen Chamber [▶ 70]
- Mounting the Specimen Holder [▶ 71]
- Evacuating the Specimen Chamber [ 72]

# 6.2.2.1 Displaying the Crossbeam SEM Control Panel

- **Prerequisite** ✓ The SmartSEM user interface is started.
  - 1. From the Menu Bar, select Tools > Goto panel.
    - → The Panel Configuration Bar is displayed. It contains an alphabetical list of functions.
  - 2. Double-right-click Crossbeam SEM Control.
    - → The Crossbeam SEM Control panel is added to the docking panel.

# 6.2.2.2 Driving the Stage to a Low Position

- **Prerequisite** The stage is initialized.
  - 1. In the Crossbeam SEM Control panel, select the Imaging tab.
  - 2. In the Detector / Active Channel section, select TV from the Signal A drop-down list.
    - → The inside of the specimen chamber is visible in the **Image Area**.
  - 3. In the Crossbeam SEM Control panel, select the **Stage** tab.
  - 4. Activate the **Track Z** checkbox.
    - → The current working distance (WD) is displayed in the **Data Zone**.
  - 5. If the Data Zone is deactivated, activate it via Menu Bar > View > Data Zone > Show Data Zone.
  - 6. Use the dual joystick to drive the specimen stage downwards to a low position. **NOTICE** Risk of property damage: Observe the stage movement via camera to avoid crashing.

# 6.2.2.3 Venting the Specimen Chamber

- 1. In the Crossbeam SEM Control panel, select the **Vacuum** tab.
- 2. Click Vent.
  - → The **Vent** message box is displayed.
- 3. To start venting, click Yes.
  - → The specimen chamber is purged with gaseous nitrogen.
  - → If the Stage is not initialized, a system message is displayed. Refer to *Initializing the Stage* [**>** 99].

## 6.2.2.4 Mounting the Specimen Holder

# **Safety Information**

# **MARNING**

# Suffocation hazard: Lack of oxygen

Gaseous dry nitrogen is used to vent the specimen chamber during specimen exchange. Inhaling nitrogen may cause unconsciousness.

- During specimen exchange, keep the chamber door open as short as possible.
- ▶ Do not inhale the air from within the specimen chamber.
- ▶ Ensure that the area around the microscope is sufficiently vented.
- ▶ If you begin to experience symptoms of asphyxia (for example: rapid breathing, loss of mental alertness and/or muscular coordination, depression of sensations, emotional instability, fatigue) leave the room immediately and inform the facility's safety officer.

# **A** CAUTION

# Risk of injury: Moving the specimen stage

Fingers can be trapped by the moving specimen stage.

- Always close the chamber door before moving the specimen stage.
- To remove parts fallen into or near to the stage use a tool (e.g. tweezers) instead of your fingers.

# **A** CAUTION

# Risk of injury: Closing the chamber door

Fingers can be pinched when closing the chamber door.

- Use the door handle to close the chamber door.
- Ensure not to get your fingers caught in the chamber door gap.

# **NOTICE**

# Risk of property damage: Short working distance

When opening the chamber door, the microscope or specimen can be damaged if the specimen stage is at a short working distance. If a BSD detector is inserted, it can be damaged as well.

Always move the specimen stage to a long working distance before opening the chamber door.

# **NOTICE**

# Risk of property damage: Contamination caused by fingerprints

Contamination caused by fingerprints can lead to vacuum deterioration or prolonged pumping times.

- Always wear lint-free gloves when touching the specimen, specimen holder, or stage.
- 1. Carefully open the chamber door.
- 2. If a specimen holder is mounted onto the specimen stage, remove it by sliding it out of the dovetail rails.
- 3. Mount the prepared specimen holder by sliding it into the dovetail rails. Make sure that the dovetail is placed in the correct orientation so that the flat side of the dovetail of the specimen holder is flush with the milled edge of the specimen stage.

- 4. Carefully close the chamber door.
  - → The specimen holder and the specimen inside the chamber are visible in the **Image** Area.

# 6.2.2.5 Evacuating the Specimen Chamber

- 1. In the Crossbeam SEM Control panel, select the **Vacuum** tab.
- 2. Click Pump.
  - → Several vacuum status messages display the current vacuum levels.
  - → As soon as the appropriate vacuum level is achieved, the vacuum status message Vac Status = Ready is displayed.
     This may take up to 5 minutes.

# 6.2.3 Locating the Specimen

**Overview** The procedure contains the following steps:

- Positioning the Stub under the Electron Beam [▶ 72]
- Moving the Specimen to the Proper Height [▶ 73]

# 6.2.3.1 Positioning the Stub under the Electron Beam

# **Safety Information**

# **NOTICE**

# Risk of property damage: Driving the stage

While the stage is driven manually, there is a risk of damaging the objective lens and/or the specimen.

- ▶ Ensure not to hit the objective lens while driving the stage.
- Monitor the moving stage in TV mode.
- To stop the moving stage immediately, press **F12** or press the **Break** push button of the dual joystick panel.
- Manually lower the stage before you open the chamber door. Alternatively, activate the Z move on Vent checkbox in the Stage tab of the Crossbeam SEM Control panel.
- 1. In the Stage Navigation Bar, select Stage Sideview from the upper drop-down list and Stage Topview from the lower drop-down list.
  - INFO: To open the Stage Navigation Bar, navigate to View > Toolbars and activate Stage Navigation Bar (for Widescreen users). Alternatively, you can access the Stage Navigation Bar via Stage > Navigation.
- 2. Click Settings.
  - → The Stage Navigation Settings dialog is displayed.
- 3. In the Stage Navigation Settings dialog, click Show Holder Gallery.
  - → The Sample Holder Gallery dialog is displayed.
- 4. In the Sample Holder Gallery dialog, click the specimen holder you are using.
- 5. Activate the Is Available checkbox.
- 6. Close the Sample Holder Gallery dialog.
- 7. Close the Stage Navigation Settings dialog.
- 8. In the Stage Topview section of the Stage Navigation Bar, spot the stub with the specimen you want to observe.
- 9. To drive the stub directly under the electron beam, double-click the stub.

#### 6.2.3.2 Moving the Specimen to the Proper Height

- 1. In the Stage Navigation Bar, drag the Zoom View slider to the right end, so that the schematics are zoomed in.
- 2. In the Crossbeam SEM Control panel, select the Imaging tab.
- 3. In the Detector / Active Channel section, select USB TV1 from the Signal A drop-down list.
  - → The inside of the specimen chamber is visible in the Image Area.
- 4. Use the dual joystick to carefully move up the stage so that the stub you are using is in the center of the upper schematic.

# **NOTICE** Risk of property damage: Observe the camera image in order not to crash into the pole piece.

→ INFO: After loading the specimen, there is the possibility to use the Sample Type Selection Function to automatically set a number of key parameters. Refer to Using the Sample Type Selection Function.

# 6.2.4 Switching on the Gun

# **NOTICE**

# Risk of property damage: Schottky field emitter

If the Schottky field emitter is switched on and off too frequently or inappropriately, its lifetime is reduced.

- Avoid switching off the gun during the working week.
- ▶ Use Standby mode for the weekend or a break of up to a week.
- When using the Standby mode, activate the Partial Vent on Standby function.

- **Prerequisite** ✓ The chamber and the gun head have been evacuated.
  - 1. In the right part of the **Status Bar**, verify whether the gun is switched on or off.
    - → If Gun: ✓ or All: ✓ is displayed, the gun is already switched on and you can skip the following steps.
    - → If Gun: X is displayed, the gun is switched off. Follow the operating steps within this chapter.
  - 2. In the Crossbeam SEM Control panel, select the **Vacuum** tab.
  - 3. Verify that the **EHT Vac ready** readout is **EHT Vac ready = Yes**. If not, the correct vacuum is not achieved. Check if the Pump procedure has been completed.
  - 4. In the right part of the **Status Bar**, click Gun: ★.
    - → The pop-up menu for vacuum, qun, and EHT activation is displayed.
  - 5. Click Gun On.
    - → The gun runs up.
    - → This may take up to 5 minutes.

# 6.2.5 Switching on the EHT

**Purpose** When you switch on the EHT, the gun starts emitting electrons.

- **Prerequisite** ✓ The chamber and the gun head have been evacuated.
  - ✓ The gun has been switched on.
  - 1. In the Crossbeam SEM Control panel, select the Control tab.
  - 2. Double-click the EHT Target readout.
    - → The EHT Target window is displayed.
  - 3. In the input field, enter 10 and click OK.
  - 4. In the right part of the **Status Bar**, click **EHT**: X.
    - → The pop-up menu for vacuum, gun, and EHT activation is displayed.
  - 5. Click EHT On.
    - → The EHT runs up to 10 kV.
    - → In the right part of the **Status Bar**, the vacuum, gun, and EHT status buttons merge to All: 🗸

#### 6.2.6 Acquiring an Image

# **Purpose**

#### Info

The following procedure describes the best way to quickly obtain an image without the control panel. You can also use the control panel to adjust aperture alignment, magnification/focus and brightness/contrast.

**Overview** The procedure contains the following steps:

- *Selecting the Column Mode and Probe Current* [▶ 74]
- *Selecting the SE Detector* [▶ 74]
- Setting a Fast Scan Speed [▶ 75]
- *Setting a Low Magnification* [▶ 75]
- Setting a Long Working Distance [▶ 75]
- *Adjusting Brightness and Contrast* [▶ 75]
- Visualizing Details on the Specimen Surface [ > 75]

# 6.2.6.1 Selecting the Column Mode and Probe Current

- 1. In the Crossbeam SEM Control panel, select the **Control** tab.
- 2. In the **Column** section, click **Normal**.
  - → The column mode is set to **Normal**.
- 3. In the **Beam** section, double-click the **I Probe** readout.
  - → The I Probe window is displayed.
- 4. In the input field, enter 300.
  - → The probe current is set to 300 pA.

# 6.2.6.2 Selecting the SE Detector

1. In the Crossbeam SEM Control panel, select the Imaging tab.

In the Detector / Active Channel section, select Signal A = SE2 from the Signal A dropdown list.

INFO: We recommend using the SE detector to obtain the first image. This detector provides a good signal-to-noise ratio even at long working distances.

#### 6.2.6.3 Setting a Fast Scan Speed

- 1. In the Crossbeam SEM Control panel, select the Imaging tab.
- 2. From the Scan Speed drop-down list, select Scan Speed = 1. INFO: The lower the scan speed number, the faster the electron beam scans across the specimen. Scan Speed = 1 allows you to get an image quickly.

# 6.2.6.4 Setting a Low Magnification

1. In the **Toolbar**, select the Magnification+Focus/Auto Focus+Stig icon.



- → The **Status Bar** displays the values for magnification and focus.
- 2. In the Status Bar, click Left: Mag =
  - → The **Mag** window is displayed.
- 3. In the **Mag** input field, enter 500.
- 4. Click OK.
  - $\rightarrow$  The magnification is set to Mag = 500 x.

#### 6.2.6.5 Setting a Long Working Distance

- 1. In the **Status Bar**, click Mid: WD =
  - → The **WD** window is displayed.
- 2. In the **WD** input field, enter 10.
- 3. Click OK.
  - $\rightarrow$  The working distance is set to **WD** = 10 mm.

# 6.2.6.6 Adjusting Brightness and Contrast

- 1. In the Crossbeam SEM Control panel, select the Imaging tab.
- In the **Detector / Active Channel** section, use the scroll bars to adjust brightness and contrast.

#### 6.2.6.7 Visualizing Details on the Specimen Surface

- 1. Select a detail on the specimen surface.
- 2. Verify the Magnification/Focus function is activated.



- 3. To adjust the magnification, hold down the left mouse button and drag the mouse within the **Image Area** in left/right direction.
  - → The current magnification is indicated in the **Status Bar**.
- 4. To adjust the focus, change the working distance. Hold down the mouse wheel and drag the mouse within the **Image Area** in left/right direction.
  - → The current working distance is indicated in the **Status Bar**.
- 5. Adjust contrast and brightness again.

# 6.2.7 Optimizing the Image

**Purpose** Once you have generated an initial image, you can adjust various parameters to optimize the image.

#### Info

The following procedure describes the best way to quickly optimize the image without the control panel. You can also use the control panel to adjust aperture alignment, magnification/ focus and brightness/contrast.

**Overview** The procedure contains the following steps:

- Adjusting the Magnification [▶ 76]
- Moving the Field of View at High Magnifications [▶ 76]
- Limiting the Scan Field [▶ 77]
- Aligning the Aperture [▶ 77]
- Selecting the Scan Speed [▶ 77]
- Correcting Astigmatism [▶ 78]

#### 6.2.7.1 Adjusting the Magnification

- 1. To switch to the Fine mode, in the Status Bar, click Coarse .
  - → The Coarse button changes to Fine .
- 2. Step by step, raise the magnification up to Mag 50,000 x and focus in between. To adjust the magnification and the focus, hold down the left mouse button or the mouse wheel, respectively, and drag the mouse within the Image Area.

# 6.2.7.2 Moving the Field of View at High Magnifications

**Purpose** If you want to move the field of view at high magnifications, use the Beam Shift function instead of moving the stage.

- 1. In the Crossbeam SEM Control panel, select the Control tab.
- 2. In the Alignment section, click Beam Offset.
- 3. To shift the beam, in the Beam Offset navigation box, use the scroll bars or the red marker.



### 6.2.7.3 Limiting the Scan Field

#### **Prerequisite**

- Adjusting the size and position of the small frame (reduced raster) requires the license RE-DUCED.
- 1. In the Toolbar, click the Reduced Raster/Apertures icon.



- → A small scan frame is displayed. This frame defines the specimen area to be scanned by the electron beam.
- → The image outside the scan frame is frozen.
- 2. To change the position of the scan frame, click on the green border line and use the mouse to drag and drop the frame.
- 3. To change the size of the scan frame, click on the small blue squares on the green border line and drag them to the desired size.
- 4. Focus the image in the reduced raster.

# 6.2.7.4 Aligning the Aperture

- 1. In the Crossbeam SEM Control panel, select the Control tab.
- 2. In the Alignment section, click Focus Wobble.

  INFO: Focus wobble is a function that sweeps the acceleration voltage. If the aperture is misaligned, a lateral and vertical shift can be observed.
  - → The Focus Wobble window is displayed.
- 3. To adjust the wobble intensity, use the Wobble Amplitude scroll bar.
- 4. To accelerate the wobble speed, activate the Wobble Fast checkbox.
- 5. In the Control tab, click Aperture.
- 6. In the Aperture Align navigation box, use the scroll bars or the red marker to adjust the aperture alignment until there is no movement of the detail in X- and Y-direction. INFO: The specimen detail should just be pulsating without shifting.
- 7. In the Focus Wobble window, click OFF to deactivate focus wobble.
  - → The Focus Wobble window closes.
- 8. Refocus the image.

# 6.2.7.5 Selecting the Scan Speed

1. In the Toolbar, from the Faster/Slower drop-down list, select Scan Speed = 7.



Alternatively, in the Crossbeam SEM Control panel, select the Imaging tab, and from the Scan Speed drop-down list, select Scan Speed = 7.

- $\rightarrow$  The scan speed is set to Scan Speed = 7.
- 2. Bring the image into focus.

# 6.2.7.6 Correcting Astigmatism

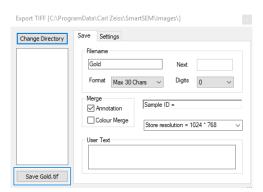
- 1. Ensure that the Reduced Raster function is active.
- 2. Select a detail (e.g. a mark or an edge) on the specimen surface. Ensure that the selected detail is in the raster. You can move the stage or shift the beam for this purpose.
- 3. In the Crossbeam SEM Control panel, select the Control tab.
- 4. Click Stigmator.
- 5. In the Stigmation navigation box, use the scroll bars or the red marker to obtain the sharpest possible image.
  - INFO: The specimen detail should just be pulsating without shifting.
  - INFO: To obtain optimum results, alternately correct focus and astigmatism.
- 6. To deactivate the reduced raster, in the Toolbar, click the Reduced Raster/Apertures icon.

# 6.2.8 Saving the Image

1. In the Toolbar, click the Freeze:Unfreeze/Scanning icon.



- → A red dot at the right bottom of the Image Area indicates that the image is frozen.
- 2. From the Menu Bar, select File > Save Image.
  - → The Export TIFF dialog is displayed.



- 3. To change the save path, click Change Directory.
  - → A file explorer window is displayed.
- 4. To confirm the selected path, click Select Folder.
- 5. Enter the filename in the Filename input field.
- 6. Click Save <file name>.tif.
- 7. To continue imaging, click the Freeze:Unfreeze/Scanning icon.



# 6.3 Modifying Gun Parameters

#### 6.3.1 Selecting the Gun Mode

**Purpose** The microscope can operate in different gun modes:

- Normal
- Imaging
- Analytic

#### **Normal Gun Mode**

In Normal gun mode, the temperature of the Schottky emitter (gun / filament) and the extraction voltage are optimized for a long lifetime of the Schottky emitter. Normal gun mode is suitable for most applications.

#### **Imaging Gun Mode**

In Imaging gun mode, the temperature of the Schottky emitter and the extraction voltage are reduced in comparison to the Normal gun mode. This leads to a reduction of the energy spread of the primary electrons. Overall, the probe current in Imaging gun mode is about half the probe current in Normal gun mode.

Imaging gun mode is especially useful at low kV or at high magnifications to reduce chromatic aberration and to achieve a better resolution. Switching from Normal gun mode to Imaging gun mode is useful for reducing the probe current without any need for beam adjustments.

#### **Analytic Gun mode**

In Analytic gun mode, the Schottky emitter runs at default temperature but the extraction voltage is increased in comparison to the Normal gun mode. This leads to a higher probe current. Overall, the probe current in Analytic gun mode is about twice the probe current in Normal gun mode.

The Analytic gun mode is especially useful for applications which require high intensities (e.g. WDX).

# Info

After switching the gun mode, you can immediately work with the selected gun mode. For applications, which require a high probe current stability, wait 24 hours until a stability of 0.2 %/ h is reached. It is recommended not to change the gun mode during quantitative specimen analysis.

- 1. From the Menu Bar, select Tools > User Preferences.
  - → The User Preferences dialog is displayed.
- 2. Select User > Expert Gun Mode.
- 3. Click in the Value field and select Yes.
- 4. Close the User Preferences dialog.
- 5. In the Panel Configuration Bar, double-click Crossbeam SEM Control.
- 6. In the Crossbeam SEM Control panel, select the Control tab.
- 7. In the Beam section, click one of the following buttons:

To switch to Imaging gun mode, click Imaging.

To switch to Normal gun mode, click Normal.

To switch to Analytic gun mode, click Analytic.

INFO: For maximum probe current, also check the alignment of the gun.

INFO: If you use the Analytic gun mode, then the lifetime of the emitter is reduced.

# 6.3.2 Setting the Probe Current

Purpose With the GEMINI II column, you can set a lower probe current to analyze surface details at a high resolution or higher probe currents for analytical purposes, e.g. to analyze the material of the specimen.

#### Info

The maximum achievable probe current depends on the currently selected EHT and the installed aperture configuration.

- 1. In the Crossbeam SEM Control panel, select the Control tab.
- 2. Double-click the I Probe readout.
  - → The I Probe window is displayed.
- 3. In the input field, enter the desired value.

# 6.3.3 Measuring the Probe Current

Purpose Measuring the probe current using the Faraday cup ensures that the current displayed in the software equals the incident probe current. The Faraday cup consists of a strongly absorbing material with a cavity covered by a small aperture. If the beam is focused in this cavity, no secondary electrons and no backscattered electrons leave the Faraday cup.

#### **Parts and Tools**

Designation	Part no.
Faraday cup	348342-8055-000

- 1. Load the Faraday cup into the specimen chamber.
- 2. Evacuate the specimen chamber.
- 3. Switch on the gun.
- 4. Switch on the EHT.
- 5. From the Panel Configuration Bar, select Specimen Current Monitor.
  - → The Specimen Current Monitor window is displayed.
- 6. Activate the Stage Bias checkbox.
  - → This activates the touch alarm that helps to avoid collisions of the stage.
- 7. Move the stage to the position of the Faraday cup.
- 8. Acquire an image of the Faraday cup.
- 9. Activate the Spot checkbox.
  - → Green crosshairs are displayed on the image. The crosshairs indicate the position of the beam spot.
- 10. Grab the crosshairs and move them into the hole of the Faraday cup.
  - → The probe current is measured continuously.
  - → The measured probe current is displayed in the Specimen I readout.

# 6.3.4 Changing the Extractor Voltage

Purpose The Extractor voltage is preset by the factory or by the ZEISS service representative. Within certain limits, the operator may carefully increase the extractor voltage in order to optimize the probe current for particular applications.

#### Info

Use a Faraday cup to measure the probe current when changing the extractor voltage.

# Info

The newly set extractor value is only valid for the current work session. After a restart of the SmartSEM software, the microscope restores the nominal extractor voltage.

# Info

Reducing the extractor voltage may impair the performance and resolution of the microscope.

- Avoid reducing the extractor voltage.
- If at all, reduce the extractor voltage only for a short time (1-2 h) and by maximum 500 V.

- **Prerequisite** ✓ The user privilege Extractor is required to change the extractor voltage.
  - 1. From the Menu Bar, select Beam > Gun Setup.
    - → The Gun Service dialog is displayed.
  - 2. To increase the extractor voltage, double-click the Extractor V Target readout.
    - → The Extractor V Target window is displayed.
  - 3. Enter a higher value.
  - 4. Click OK.

# 6.4 Working with Different Aperture Configurations and Beam Modes

# 6.4.1 Determining the Installed Aperture Configuration | Gemini II Column

Purpose The achievable maximum probe current depends on the type of installed anode aperture. The type of aperture installed on the microscope can be determined via SmartSEM.

For the Gemini II column, two different column configurations are available:

40 nA high resolution configuration

Anode aperture diameter	Probe current	Typical application
55 μm*	10 pA to 40 nA	High resolution

100 nA high current configuration

Anode aperture diameter	Probe current	Typical application
90 μm*	10 pA to 100 nA	Combined high resolution and analytical investigations

<sup>\*</sup> Calibration value: deviation of 10 % possible

#### Info

If you wish to change the installed configuration of your microscope, contact your local ZEISS service representative.

- 1. From the Menu Bar, select View > SEM Status.
  - → The SmartSEM Status dialog is displayed.
- 2. In the Select tab, click Anode Aperture Diameter.
- 3. Select the Display tab.
  - → The parameter Aperture Size is displayed.

# 6.4.2 Selecting the Column Mode

**Purpose** With the Gemini column, different column modes are available.

The Normal mode is the standard imaging and analytical mode with a high flexibility for different applications. Overview mode provides a large field of view.

- 1. In the Crossbeam SEM Control panel, select the Control tab.
- 2. In the Column section, select between: Normal and Overview
- 3. If required, adjust the Depth of Field slider.

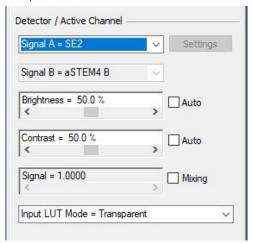
# 6.5 Finding Appropriate Detector Settings

# 6.5.1 Selecting a Detector

You need to select an appropriate detector depending on the application and the pressure mode. In addition to the standard SE detector, several optional detectors are available.

For information on special set-up procedures for the detectors, see:

- Setting up the InLens SE Detector [> 83]
- Setting up the SE Detector [▶ 83]
- Setting up the SESI Detector [▶ 85]
- Setting up the aBSD/BSD Detector [▶ 86]
- Setting up the EsB Detector [▶ 84]
- Setting up the aSTEM/STEM Detector [▶ 88]
- Setting up the CL Detector [▶ 91]
- 1. Select the Imaging tab of the Crossbeam SEM Control panel.
- Select the detector from the Signal A dropdown list.



# 6.5.2 Setting up the InLens SE Detector

**Purpose** The InLens SE detector collects the SE signal, acquiring mainly information about surface topography.

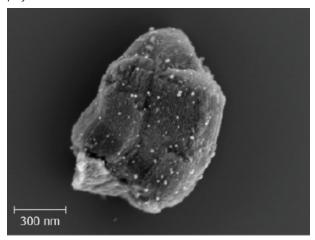


Fig. 30: Silver nanoparticles embedded in zeolite, imaged at 1.5 kV.

The following settings are recommended for the InLens SE detector:

ЕНТ	Typical WD	Recommended WD
20 V – 10 kV	0–5 mm	Short working distances are preferable for
10 kV – 20 kV	2-5 mm	good detection efficiency

# Info

Avoid strong specimen tilting for the InLens SE detector.

- 1. In the Crossbeam SEM Control panel, select the Imaging tab.
- 2. From the Signal A drop-down list, select InLens.
- 3. Adjust the EHT and the working distance (WD) according to the suggestions in the table in order to optimize the image.

# 6.5.3 Setting up the SE Detector

**Purpose** The SE detector collects the SE signal, highlighting the topography of the specimen.



Fig. 31: An eledone tentacle

The following settings are recommended for the SE detector:

EHT	Typical WD	Collector Voltage
500 V – 5 kV	2–8 mm	<ul> <li>Adjustable from –250 V to +400 V</li> </ul>
5 kV – 30 kV	min. 6 mm	<ul> <li>Standard applications: +300 V</li> </ul>
		At a high magnification, you can optimize the image by varying the collector voltage.
		<ul><li>Pseudo-backscattered (BSE) image: -250 V to -50 V</li></ul>
		This produces a topogaphic image of the sample with no material contrast.

- 1. In the Crossbeam SEM Control panel, select the Imaging tab.
- 2. From the Signal A drop-down list, select SE2.
- 3. Adjust the EHT, working distance (WD), and collector voltage according to the suggestions in the table in order to optimize the image.

# 6.5.4 Setting up the EsB Detector

Purpose The EsB detector can be used to collect the backscattered electrons (BSE) signal. The BSE signal contains information about the material contrast. In the final image, heavy elements are represented by brighter pixels and light elements are represented by darker pixels.

By adjusting the filtering grid, energy-selected BSE images can be obtained. If the filtering grid voltage is set to 0, SE and BSE mixed images can be acquired.

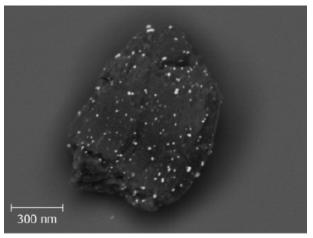


Fig. 32: Silver nanoparticles embedded in zeolite, imaged at 1.5 kV

The following settings are recommended for the EsB detector:

EHT	Typical WD	Filtering Grid
500 V – 10 kV	0–5 mm	EsB Grid > 400 V to filter out the SE signal
20 V – 500 V	0–3 mm	EsB Grid = 0 V for use as an additional SE detector

- 1. In the Crossbeam SEM Control panel, select the Imaging tab.
- 2. From the Signal A drop-down list, select ESB.
- 3. Adjust the EHT, working distance (WD), and EsB Grid according to the suggestions in the table in order to optimize the image.

# 6.5.5 Setting up the SESI Detector

**Purpose** The SESI detector is optionally available and replaces the chamber SE detector.

The SESI detector enables you to acquire both secondary electron images and FIB secondary ion images.

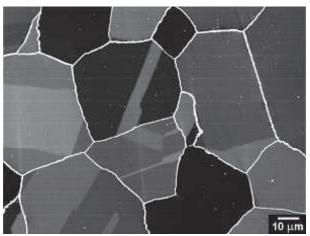


Fig. 33: Intergranular corrosion in an nickel based superalloy

The following settings are recommended for the SESI detector:

• Settings when working in SE mode, secondary electron imaging, FIB mode = SEM:

EHT	Typical WD	Collector Voltage
100 V – 30 kV	2–12 mm	<ul> <li>Adjustable from 0 V to +1500 V</li> </ul>
	Typically 5 mm	<ul> <li>Best detection: +300 V to +400 V</li> </ul>

Settings when working in SE mode, secondary electron imaging, FIB mode = FIB:

EHT	Typical WD	Collector Voltage
2 kV – 30 kV	Coincidence point	<ul> <li>Adjustable from 0 V to +1500 V</li> <li>Best detection: +300 V to +400 V</li> </ul>

• Settings when working in ion mode, secondary ions imaging, FIB mode = FIB:

EHT	Typical WD	Collector Voltage
2 kV – 30 kV	Coincidence point	<ul> <li>Adjustable from –4 kV to +0 kV</li> <li>Best detection: Around –4 kV</li> </ul>

- 1. In the FIB Toolbar, from the Imaging Mode drop-down list, select an imaging mode, e.g. FIB mode = SEM.
- 2. In the Crossbeam SEM Control panel, select the Imaging tab.
- 3. From the Signal A drop-down list, select SESI.
  - → By default, secondary electrons are detected.
- 4. In order to detect secondary ions, in the Imaging tab, activate the SESI Mode checkbox.
- 5. Adjust the EHT, working distance (WD), and collector voltage according to the suggestions in the table in order to optimize the image.

# 6.5.6 Setting up the aBSD/BSD Detector

**Purpose** The aBSD detector is a pneumatically retractable backscattered electron detector which is inserted below the objective lens and is used for high efficiency and angle selective (aBSD) material characterization.

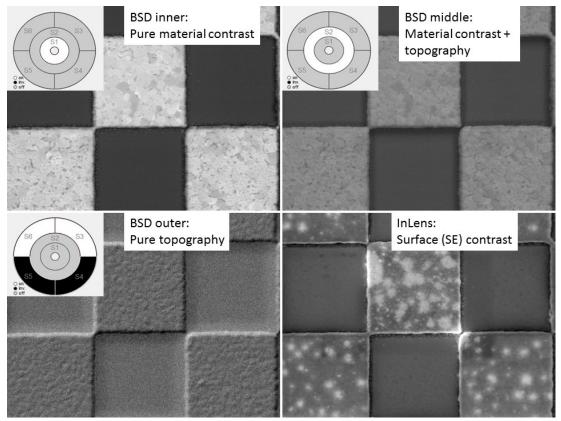
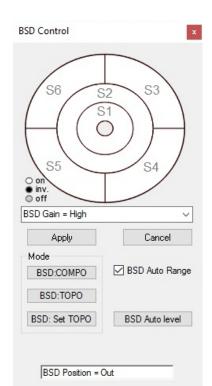


Fig. 34: Quad mode showing different contrast on different segments of the aBSD detector: Segment S1: Pure material contrast (top left), Segment S2: Material contrast and topography (top right), Segments S3 to S6: Pure topography (bottom left). For comparison: Surface contrast seen with the InLens SE detector (bottom right)

The following settings are recommended for the aBSD detector:

EHT	Typical WD	Detector Settings
0.5–30 kV	5–12 mm	Compositional mode for obtaining an image that is high in atomic number contrast
		Use topographic mode for showing surface details
		Use individual settings for channeling contrast
		Make use of different concentric rings of the aBSD detector to get angular resolved BSE images
		Use high or very high detector gain for low accelerating voltage and/or low beam current
		The EHT should be bigger than 2 kV to achieve a significant detection efficiency.

From the Panel Configuration Bar, select BSD Control.
 The BSD Control panel enables you to change the polarity of the segments, select BSD modes, and set the BSD gain.



BSD out

BSD Stop

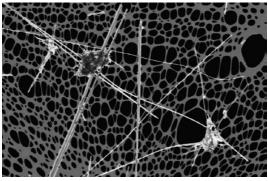
→ The BSD Control panel is displayed.

- 2. In the BSD Control panel, click BSD in to insert the aBSD detector.
  - → The stage is lowered by 20 mm to give space for the detector to be inserted.
  - → The detector is inserted.
- 3. In the Crossbeam SEM Control panel, select the Imaging tab.
- 4. From the Signal A drop-down list, select aBSD1 or aBSD4 A depending on your detector type and configuration.
  - INFO: A refers to the video channel. B, C, and D are also available if you have the four-channel version.
- 5. Adjust the EHT and the working distance (WD) according to the suggestions in the table in order to optimize the image.
- 6. In the BSD Control panel, click a quadrant symbol to toggle its status between on (white), inverted (black), and off (gray).
- 7. To choose the respective mode, click BSD: COMPO or BSD: TOPO. The default setting for BSD is BSD: COMPO. All six segments (S1–S6, aBSD) or four segments (S1–S4, BSD) are set to **on** and an image that is high in atomic number contrast is obtained.
  - The default mode for BSD: TOPO is S3 on, S4 on, S5 inv and S6 inv (aBSD) and S1 on, S2 on, S3 inv and S4 inv (BSD).
- 8. If you want to change the default setting to BSD: TOPO, click BSD: Set TOPO.
- 9. From the BSD Gain drop-down list, select Low, Medium, High, or Very High. INFO: Since the detector has a limited speed, it is recommended to use scan speed 6 or higher (slower), especially at small magnifications. The lower the gain is, the faster is the detector.

# 6.5.7 Setting up the aSTEM/STEM Detector

Purpose The aSTEM/STEM detector is used for compositional imaging or topographical imaging of ultrathin specimens. The aSTEM/STEM detector is available either with one video output channel (aSTEM1) or with four video output channels (aSTEM4). The aSTEM detector is optionally available.

The aSTEM/STEM detector is equipped with several separate diode segments. The signals of the segments can individually be added to or subtracted from the output signal in order to allow different STEM imaging modes, e.g. bright field (BF) or oriented dark field (ODF). The most commonly used STEM imaging modes are predefined and can be selected from a drop-down menu in the STEM Control panel.



**STEM Control** 

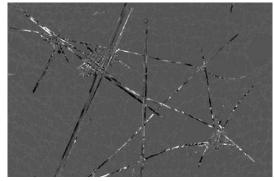
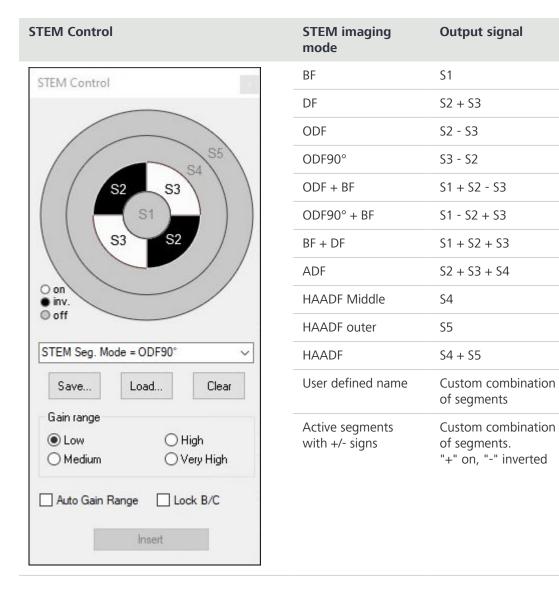
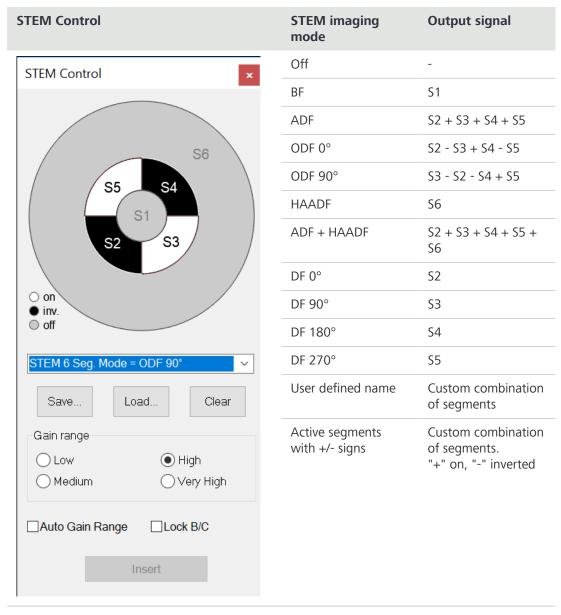


Fig. 35: Asbestos, oriented darkfield (ODF) image captured with an aSTEM4 detector (left), ODF image showing real information about bending and lattice defects within each fiber (right).

STEM Contro	ol	
S2		S3 \
	S1	
1		-
S:	3	S2
on inv.		
on inv. off	Mode = ODF90	·
on inv. off  STEM Seg. 1		
on inv. off  STEM Seg. I  Save  Gain range	Mode = ODF90 Load	Clear
on inv. off  STEM Seg. 1	Mode = ODF90 Load	·
STEM Seg.  Save  Gain range  Low  Medium	Mode = ODF90 Load	Clear ) High ) Very High

STEM imaging mode	Output signal
BF	S1
DF	S2 + S3
ODF	S2 - S3
ODF90°	S3 - S2
ODF + BF	S1 + S2 - S3
ODF90° + BF	S1 - S2 + S3
BF + DF	All on
User defined name	Custom combination of segments
Active segments with +/- signs	Custom combination of segments. "+" on, "-" inverted





- 1. In the Crossbeam SEM Control panel, select the Imaging tab.
- 2. For displaying several channels of a aSTEM/STEM detector simultaneously, from the Menu Bar, select Scanning > Quad Mode.
  - → The Image Area is divided into 4 zones.

    To select a detector for a zone, click in the zone.

    An anchor symbol is displayed in the selected zone.
- 3. From the Signal A drop-down list, select a STEM detector, e.g. aSTEM1.
- 4. In the Panel Configuration Bar, double-click STEM Control.

  To open the Panel Configuration Bar, from the Menu Bar, select Tools > Goto Panel.
  - → The STEM Control dialog is displayed. In the upper section, the STEM Control dialog displays the status of the diode segments. The status is either on (white), inverted (black), or off (gray).
- 5. Either select a STEM imaging mode from the STEM Seg. Mode/STEM 6 Seg. Mode drop-down list or click a custom selection of diode segments to toggle its status between on, inverted, and off.
- 6. Set the Gain range. Select between Low, Medium, High, or Very High.
- 7. For displaying several channels of a aSTEM/STEM detector simultaneously, repeat steps 3 to 6 for the other display zones.

# 6.5.8 Setting up the CL Detector

**Purpose** The CL detector is optionally available.

The CL detector collects visible or ultraviolet light and is especially useful for internal structural examinations of rocks, ceramics, and semiconductors.

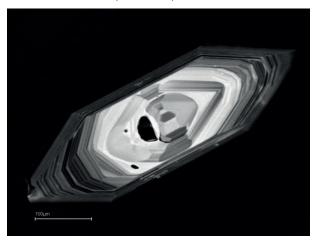


Fig. 36: Zircon grains

The following settings are recommended for the CL detector:

ЕНТ	Typical WD
5 kV – 30 kV	6–10 mm
	(min. 4 mm)

- 1. In the Crossbeam SEM Control panel, select the Imaging tab.
- 2. From the Signal A drop-down list, select CL.
- 3. Adjust the EHT and the working distance (WD) according to the suggestions in the table in order to optimize the image.

# 6.6 Shutting down the System

# 6.6.1 Finishing the Work Session

# **NOTICE**

# Risk of property damage: Schottky field emitter

If the Schottky field emitter is switched on and off too frequently or inappropriately, its lifetime is reduced.

- Avoid switching off the gun during the working week.
- Use Standby mode for the weekend or a break of up to a week.
- When using the Standby mode, activate the Partial Vent on Standby function.

- **Prerequisite** ✓ The microscope is in ON mode.
  - 1. In the Crossbeam SEM Control panel, select the Gun tab.
  - 2. Activate the EHT Off @ Log Off checkbox.
  - 3. Activate the Leave Gun On at Shutdown checkbox.
  - 4. Only when interrupting work for longer periods between 2 and 7 days: In the Vacuum tab activate the Partial Vent on Standby checkbox.
    - → This maintains the gun vacuum, and switches off and protects the turbo pump.

- 5. Exit the SmartSEM user interface. Refer to Exiting the SmartSEM User Interface [ > 92].
- 6. Close all programs and software.
- 7. Select Windows start button > Power icon > Shut down.
- 8. At the front of the plinth, press the **Standby** button.
  - → The microscope switches to Standby mode.

#### 6.6.1.1 Exiting the SmartSEM User Interface

- 1. From the Menu Bar, select File > Exit.
  - → A system message is displayed.
- 2. Click Yes.
- 3. Close the EM Server.
  - → A system message is displayed.
- 4. Click Yes.

# 6.6.2 De-energizing the Microscope

# Prerequisite ✓ The microscope is in Standby mode, see Finishing the Work Session [▶ 91]

- 1. To switch to Off mode, press the **Off** button at the front of the plinth.
- → The yellow **Standby** button blinks during shut down.
  - → When all subsystems are fully deactivated, the **Off** button lights up red permanently.
  - → Computer, electronic components, and vacuum system are switched off.
  - → The electron optical column is partially vented.
  - → A 24 V auxiliary voltage is still present to restart the microscope.
- 2. To cut off the compressed air supply, close the compressed air main shut-off valve.
- 3. To cut off the nitrogen supply, close the nitrogen main shut-off valve.
- 4. To cut off the cooling water supply, close the main shut-off valve for water.
- 5. Set the **MAIN** switch to the Off position.
  - → All power is cut off from the microscope.
- 6. To disconnect the power connection at the facility installation, remove the power plug (male connector) from the socket (female connector).
- 7. To secure the microscope against accidental re-activation, refer to *Performing a Lockout/Tagout* [ > 93].

# See also

- ☐ Finishing the Work Session [▶ 91]
- Performing a Lockout/Tagout [▶ 93]

# 6.6.3 Performing a Lockout/Tagout

The Lockout/Tagout (LOTO) procedure defines the process by which the microscope is isolated from potential hazards associated with the unexpected release of hazardous energy. This procedure needs to be performed when service, maintenance work, or unscheduled repairs can cause exposure to any form of hazardous energy.

#### Info

The customer is responsible for providing instructions on how to operate the energy-isolating devices properly.

- **Prerequisite** ✓ The microscope has been de-energized.
  - 1. Verify that the microscope has been de-energized properly.
  - 2. To secure the microscope against accidental re-activation, lock the energy-isolating devices.

# 6.7 Performing an Emergency Shutdown

# **NOTICE**

# Risk of property damage: Components in the high voltage circuitry

When the microscope, especially the qun, is fully on, an abrupt shutdown of all electrical supplies may damage some components in the high voltage circuitry, mainly the cathode.

- Use the emergency off only in an emergency situation with personnel injury.
- 1. Depending on whether the EMO option is installed on your microscope or not, operate the respective control element.
  - If the EMO option is installed, press the **EMO** button on the top of the plinth. If the EMO option is not installed, set the MAIN switch at the rear side of the plinth to the OFF position.

# 7 Maintenance and Repair

#### 7.1 Maintenance Work

The preventive maintenance is performed by the ZEISS service representative and includes the following items:

- Inspection
- Preventive maintenance work
- Change of consumables and chemicals
- Equipment test
- Verification run

#### Info

The maintenance work is accomplished according to standardized maintenance plans and is recorded by the ZEISS service representative.

# 7.2 Maintenance Intervals

The maintenance intervals depend on the period of application of the device:

- 24 hours, 7 days a week: semiannually
- 8 hours, 5 days a week: annually

#### Info

Keep track of maintenance work and contact the ZEISS service representative in time.

A list of ZEISS locations and authorized service partners can be found at:

http://www.zeiss.com/microscopy

# 7.3 Change of Consumables and Chemicals

The change of consumables and chemicals has to be performed by a ZEISS service representative at mandatory intervals.

The times scheduled are designed for the maximum equipment performance level (i.e. 24 h per day of permanent operation).

Interval	Component/Part
Every 6000 h <sup>1</sup> (filament on)	Field emission gun (filament) <sup>1</sup>
Yearly or as required  (and after exchange of field emission gun)	<ul> <li>Multihole/singlehole aperture</li> <li>Anode aperture</li> <li>Extractor aperture</li> <li>Anode aluminum seal</li> <li>Copper seal at gun head</li> </ul>
Yearly or as required	Tip seal of the pre-vacuum pump
Yearly performance check	<ul><li>SE detector</li><li>InLens SE detector</li></ul>

Interval	Component/Part
	<ul><li>EsB detector</li></ul>
As required, approx. 3000 μAh	<ul><li>Ion source</li><li>FIB apertures</li></ul>
If used up	Precursors

<sup>&</sup>lt;sup>1</sup> There is no warranty on field emission guns; manufacturers do not guarantee any lifetime.

Tab. 3: Schedule for the change of consumables

# 8 Troubleshooting

# 8.1 Overview

The following table provides hints for solving common problems. If you cannot solve the problem or if you are unsure about a certain technical difficulty, contact your local ZEISS service representative.

Keyword	Symptom	Cause	Remedy
Drift Specimen seems to be moving.	<ul><li>Charging effects.</li><li>Nonconductive specimen.</li></ul>	<ul> <li>Ensure proper conduction of the specimen.</li> <li>Optimize specimen preparation.</li> <li>Apply a charge compensation method.</li> </ul>	
		Stub not correctly fixed by screw.	Fix the stub correctly.
EHT	EHT cannot be switched on.	CAN communication has failed.	Refer to <i>Checking the CAN</i> Communication [ > 99].
	The workstation has crashed.	CAN communication has failed.	Refer to <i>Checking the CAN Communication</i> [ > 99].
FIB	Emission is unstable.	Ion source needs to be regenerated.	Refer to Regenerating the Ion Source by Heating [ 106].
		Ion source may be used up ( $> 3000 \mu Ah$ ).	Contact the ZEISS service representative to have the ion source replaced.
FIB No emission.	No emission.	Ion source needs to be regenerated.	Refer to Regenerating the Ion Source by Heating [> 106].
		Ion source may be used up.	Contact the ZEISS service representative to have the ion source replaced.
FIB No image.	Aperture position is not correct.	Initialize the FIB aperture in the FIB tab of the FIB Control panel.	
		Align the aperture in the Align tab of the FIB Control panel.	
		Column conditions have deteriorated, charging effects occur.	Start a purging process in the <b>Options</b> tab of the <b>FIB Control</b> panel.
		Gun valve is closed.	Open the gun valve in the <b>FIB</b> tab of the <b>FIB Control</b> panel.
FIB	Emission current is too high (e.g. 4 or 5 μA) for more than 30 min.	Ion source needs to be regenerated.	Refer to Regenerating the Ion Source by Heating [ 106].

Keyword	Symptom	Cause	Remedy
		Automatic regulation of the emission current is deactivated.	Activate the <b>Regulate</b> checkbox in the <b>FIB</b> tab of the <b>FIB Control</b> panel.
		Extractor target is not set to an appropriate value.	Change the extractor target. Refer to <i>Manually</i> Finding a New Extractor  Value [* 107].
			Open the <b>Gun Monitor</b> and record the parameters <b>FIB Suppressor Target</b> and <b>FIB Emission I</b> and send it to your ZEISS service representative.
FIB	Suppressor voltage is approaching 0 V or 2 kV.	Ion source needs to be regenerated.	Refer to <i>Regenerating the Ion Source by Heating</i> [• 106].
FIB	Misalignment of struc- tures when milling with different FIB probe cur- rents.	Beam shift for the probe currents is not adjusted.	Adjust the beam shift correction for the relevant FIB probe currents.
Image quality	Image quality gets worse, but there is no change in total emission current.	Field emission gun has been damaged due to arcing.	Contact your local ZEISS service representative to have the field emission gun replaced.
	Image is noisy and noise reduction methods do not help.	Field emission gun is used up.	Contact your local ZEISS service representative to have the field emission gun replaced.
	Image is bad at low EHT (e.g. 1 kV)	Working distance is too long.	Reduce the working distance to a maximum of 7 mm.
InLens image	InLens image is noisy.	Working distance is too long.	Reduce the working distance.
	No InLens image can be obtained.	EHT exceeds 20 kV.	Reduce EHT to a maximum of 20 kV.
Microscope	Microscope is dead.	Circuit breaker is tripped (lower position).	Refer to <i>Checking the Position of the Circuit Breakers</i> [• 104].
PC	Stored position of the	PC has crashed.	Restart the PC.
	specimen stage cannot be approached correctly.	Stage needs to be driven to a well-defined position.	Refer to <i>Initializing the</i> Stage [▶ 99].
SEM Gun	Gun is switched off automatically.	Gun has been switched off automatically for safety reasons since gun vacuum is worse than $2 \times 10^{-8}$ mbar	Refer to Baking out the Gun Head [ > 102].

Keyword	Symptom	Cause	Remedy
SE image	SE image is noisy.	Scintillator is used up.	Contact your local ZEISS service representative to have the scintillator replaced.
Specimen current	Specimen current is low.	Field emission gun is used up.	Contact your local ZEISS service representative to have the field emission gun replaced.
		Working distance is too short.	Enlarge working distance to about 5 mm or more.
Specimen stage	Stage does not move.	Stage needs to be initialized.	Refer to <i>Initializing the</i> Stage [▶ 99].
	Stage does not move accurately.	Stage needs to be initialized.	Refer to <i>Initializing the</i> Stage [▶ 99].
	Stored position of the specimen stage cannot be approached correctly.	Absolute stage movement is required. Stage needs to be driven to a well-defined position.	Refer to <i>Initializing the</i> Stage [▶ 99].
Stage/Joystick	Under TV control, the direction of dual joystick movement and direction of stage movement seem to be different.	TV joystick angle does not fit for the selected CCD camera.	Refer to <i>Changing the Joy-stick TV Angle</i> [▶ 100].
	Stage cannot be moved by using the joystick.	Joystick Disable checkbox is activated.	Deactivate the checkbox in the Stage tab of the Cross- beam SEM Control panel.
Temperature, water flow	Error message <b>Stage Board too hot</b> (or similar) is displayed.	Flow of cooling water is not OK.	Refer to <i>Checking the Water Flow and Temperature</i> [• 102].
Touch alarm	Touch alarm message is displayed.	Specimen or specimen holder has touched objective or wall of the specimen chamber.	Refer to <i>Resetting the</i> Touch Alarm [▶ 101].
Vacuum	Vac ready = OK is not displayed after specimen exchange.	System vacuum is bad due to a vacuum leak at the chamber door.	Check the chamber door seal for cleanliness.
			If required, refer to <i>Replacing the Chamber Door Seal</i> [> 101].
	Vac ready = OK is displayed very late after specimen exchange.	Gas ballast at rotary pump or scroll pump is activated.	Deactivate gas ballast at the pre-vacuum pump.
	Microscope does not	No nitrogen.	Check nitrogen supply.
	vent.	No compressed air.	Check compressed air supply.
	Vac ready = OK is displayed abnormally fast.	Penning gauge has not been identified correctly.	Restart the microscope.

Keyword	Symptom	Cause	Remedy
			If this does not solve the problem, contact your local ZEISS service representative.
	Gun vacuum is worse than 8 to $9 \times 10^{-9}$ mbar.	The pumping capacity of the ion getter pump decreases in the course of time, thus deteriorating the gun vacuum.	Refer to Baking out the Gun Head [▶ 102].

# **Optional Components**

Keyword	Symptom	Cause	Remedy
Flood Gun  No communication can be established with Smart- SEM	Loose cable connection.	Check the cable connection. If this does not help, contact the ZEISS service representative.	
	Flood Gun controller has an old firmware version.		
	Flood Gun is not activated in FIB Configurator.		

# 8.2 Overall System

# 8.2.1 Checking the CAN Communication

Purpose Checking the CAN Communication is useful if the microscope does not react to your commands

- 1. In the Panel Configuration Bar, double-click CAN Communication.
  - → The CAN Communication window is displayed.
- 2. If any of the values is indicated as Yes, make sure that all cable connections between workstation and PC are plugged in correctly.
- 3. If this does not help, reset the workstation as described in the instruction manual of the microscope.

INFO: If the problem persists, contact your ZEISS service representative.

#### 8.3 Chamber

# 8.3.1 Initializing the Stage

Purpose If a stored stage position cannot be approached or if the stage does not move or does not move accurately, the stage needs to be initialized.

- **Prerequisite** ✓ The specimen chamber has been evacuated, see *Loading the Specimen Chamber* [▶ 70]
  - ✓ Requires the Stage Initialise privilege
  - ✓ If there are any large specimens inside the chamber, remove them before initializing
  - 1. From the Menu Bar, select Stage > Stage Initialise.
    - → The **Initialise Stage** window is displayed.
  - 2. Confirm via Yes.
    - → The stage initialization process takes a few minutes.

→ INFO: If initialization of the stage does not solve the stage problem, contact your local ZEISS service representative.

# 8.3.2 Defining the Post Initialization Position of the Stage

Purpose You can configure the position to which the stage drives after the initialization procedure. Otherwise, the stage drives to the center position.

- **Prerequisite** ✓ Requires the Supervisor privilege.
  - 1. From the Windows start menu, select SmartSEM > SmartSEM Administrator.
    - → The SmartSEM Administrator Log on window is displayed.
  - 2. Enter user name and password.
  - 3. To confirm, click OK.
    - → The SmartSEM Administrator window is displayed showing the user list.
  - 4. Click Column/Stage.
  - 5. In the Stage Post Initialisation Position input fields, enter the desired position. Alternatively, use the dual joystick to navigate to the desired position and click Set to current position.
  - 6. To activate the function, activate the Post Init. Posn Valid checkbox.

# 8.3.3 Changing the Joystick TV Angle

Purpose In TV mode (chamberscope), it can occur that dual joystick and stage seem to move to opposite directions. This is because the selected CCD camera is installed at a certain angle relative to the stage. Thus, the camera shows a side-inverted view. To remedy this, you need to change the joystick TV angle setting in the software.

#### Info

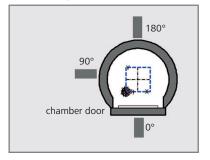
If you are working with two CCD cameras: The joystick TV angle can only be set for one CCD camera. When selecting the other CCD camera, you have to change the setting.

- **Prerequisite** ✓ Requires the Supervisor privilege.
  - 1. From the Windows start menu, select SmartSEM > SmartSEM Administrator.
    - → The SmartSEM Administrator Log on window is displayed.
  - 2. Enter user name and password.
  - 3. To confirm, click OK.
  - 4. The SmartSEM Administrator window is displayed showing the user list.
  - 5. Click Column/Stage.
  - 6. In the Stage Options section, double-click the Joystick TV Angle input field.
  - 7. Enter an angle depending on the installation location of the CCD camera.

If the CCD camera is installed at the back, enter 180°.

If the CCD camera is installed at the front, enter 0°.

If the CCD camera is installed at the side, enter 90°.



# 8.3.4 Replacing the Chamber Door Seal

**Purpose** Possible reasons for replacing the chamber door seal are the following:

- Chamber door does not close tightly
- Bad chamber vacuum

**Overview** The procedure contains the following steps:

- Venting the Specimen Chamber [▶ 70]
- Replacing the O-ring [▶ 101]
- Evacuating the Specimen Chamber [ > 72]

# 8.3.4.1 Replacing the O-ring

# ♠ WARNING

# Suffocation hazard: Lack of oxygen

Gaseous dry nitrogen is used to vent the specimen chamber during specimen exchange. Inhaling nitrogen may cause unconsciousness.

- During specimen exchange, keep the chamber door open as short as possible.
- Do not inhale the air from within the specimen chamber.
- Ensure that the area around the microscope is sufficiently vented.
- If you begin to experience symptoms of asphyxia (for example: rapid breathing, loss of mental alertness and/or muscular coordination, depression of sensations, emotional instability, fatigue) leave the room immediately and inform the facility's safety officer.

# NOTICE

#### Risk of property damage: Contamination caused by fingerprints

Contamination caused by fingerprints can lead to vacuum deterioration or prolonged pumping times.

- ▶ Always wear lint-free gloves when touching the specimen, specimen holder, or stage.
- 1. Carefully open the chamber door.
- 2. On the inside of the chamber door, remove the chamber door O-ring.

NOTICE Risk of property damage: If you use a metal tool to remove the O-ring, then you may damage the sealing surface. If necessary, then only use a plastic or wooden tool to remove the O-ring.

- 3. Inspect the groove that holds the O-ring and remove any contamination.
- 4. Insert the new chamber door O-ring.
- 5. Close the chamber door.

# 8.3.5 Resetting the Touch Alarm

Purpose To prevent damage, a touch alarm is integrated in the microscope. If the specimen or the specimen holder touches the chamber walls, the detectors, or the objective lens, the stage is stopped immediately. An audible warning sounds and an on-screen message is displayed.

- **Prerequisite** 
  The EM Server shows the message WARNING Stage Touching.
  - 1. To accept the warning, click OK.
  - 2. Move the stage in the reverse direction away from the touch.

# 8.3.6 Checking the Water Flow and Temperature

- 1. In the Panel Configuration Bar, double-click Water Flow/Temperature.
  - → The Water Flow/Temperature panel is displayed.
- 2. Check the entries.
  - → If a value is critical, it is displayed in red.

# 8.4 Column

# 8.4.1 Baking out the Gun Head

**Purpose** The pumping capacity of the ion getter pump decreases in the course of time, thus deteriorating the gun vacuum. This can be remedied by an ion getter pump bakeout as a regular maintenance procedure.

**Overview** The procedure contains the following steps:

- Switching off the Gun [▶ 102]
- Starting the Bakeout [▶ 103]
- Switching on the Gun [▶ 73]

# 8.4.1.1 Switching off the Gun

# **Safety Information**

# **NOTICE**

# Risk of property damage: Schottky field emitter

If the Schottky field emitter is switched on and off too frequently or inappropriately, its lifetime is reduced.

- ▶ Avoid switching off the gun during the working week.
- Use Standby mode for the weekend or a break of up to a week.
- When using the Standby mode, activate the Partial Vent on Standby function.
- 1. In the right part of the Status Bar, click Gun: ✓ or All: ✓.
  - → The pop-up menu for Vacuum, Gun and EHT activation is displayed.
- 2. Click Shutdown Gun.
- 3. Wait until the gun has ramped down.
  - → This may take up to 5 minutes.

#### 8.4.1.2 Starting the Bakeout

#### Info

You cannot work with the microscope while the bakeout procedure runs.

### **Safety Information**

# NOTICE

# Risk of property damage: Hot surfaces during bakeout

Parts of the enclosure in the upper range of the column may become hot during bakeout, particularly after a long bakeout cycle.

- ▶ Do not place any objects on the grids of the electron column during bakeout.
- After the bakeout procedure, let surfaces cool down before working around the column.
- Only advanced operators are allowed to perform the bakeout procedure.

- **Prerequisite** Requires the Supervisor privilege and the user level Service
  - ✓ Only advanced operators are allowed to perform the bakeout procedure
  - 1. In the Panel Configuration Bar, double-click Bakeout.
    - → The **Bakeout** dialog is displayed.
  - 2. If the Full service bakeout checkbox is available, deactivate the Full service bakeout checkbox.

INFO: Full service bakeout includes column heating that may lead to column misalignment.

- 3. From the **Bakeout** drop-down list, select a bakeout cycle.
  - For 2 hours heating / 1.5 hours cooling, select **Quick**.
  - For 8 hours heating / 1.5 hours cooling, select **Overnight**.
  - For 43 hours heating / 7 hours cooling, select **Weekend**.
  - For a cycle defined by the operator, select **User**.
- 4. To start the bakeout procedure, click **Bakeout Start**.

#### 8.4.2 Calibrating the Probe Current

Purpose This function enables you to automatically calibrate the probe currents within a few minutes. Calibrating the probe current can be necessary in the following cases:

- Before performing analytical applications (e.g. EDX, WDX)
- After changing the extractor voltage
- To improve the accuracy of the set probe current values

#### **Parts and Tools**

Designation	Part no.
Faraday cup	348342-8055-000

- **Prerequisite** ✓ The microscope has a Gemini II column
  - 1. Load the Faraday cup into the specimen chamber.
  - 2. Pump the specimen chamber.
  - 3. Switch on the electron beam.
  - 4. Set a magnification that allows transmission of the complete electron beam into the cavity of the Faraday cup through the aperture orifice.
  - 5. In the Panel Configuration Bar, double-click Probe Current Calibration.
    - → The Probe Current Calibration window is displayed.
  - 6. Activate the Spot checkbox.

- 7. Click Cal I Probe.
- 8. To confirm, click Yes.
- 9. To store the calibration, click Save.
- 10. Deactivate the Spot checkbox.

# 8.5 Power Circuit

# 8.5.1 Checking the Position of the Circuit Breakers

# **Safety Information**

# **NOTICE**

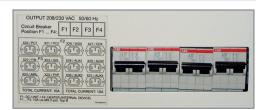
# Risk of property damage: Persisting electrical problems

Tripped circuit breakers may be a hint for an electrical problem in the microscope.

▶ If a circuit breaker keeps tripping, de-energize the microscope completely and contact your ZEISS service representative for assistance.

No.	Value	Circuit
F1	10 A	Power supply unit
F2	10 A	PC, WDX, EDX, AUX 1–4
F3	10 A	Airlock, pre-vacuum pump
F4	10 A	Internal heaters

1. Check if one of the circuit breakers on the rear side of the plinth is tripped.



2. If one of the circuit breakers is tripped, push it upwards.

# 8.6 Detectors

#### 8.6.1 Lubricating the Rod

The rod from the aSTEM and BSD4 detector mechanics needs to be lubricated once a year with TEM oil 300.

#### **Parts and Tools**

Designation	Part no.
TEM oil 300	000000-0484-955
Isopropanol	-
Lint-free cloth	-
Lint-free gloves	-

# **A** CAUTION

# Risk of injury: TEM oil 300

TEM oil 300 may be irritating to skin and eyes.

- Avoid contact with skin.
- Wear suitable gloves.
- In case of contact with the eyes, rinse immediately with plenty of water and seek medical advice.
- After contact with the skin, wash immediately with plenty of water and soap.

# **A** CAUTION

# Risk of injury: Isopropanol

Isopropanol is highly flammable and irritating to the eyes.

Vapors may cause drowsiness and dizziness.

- Wear suitable gloves.
- ▶ Keep away from sources of ignition.
- Do not smoke.
- In case of contact with the eyes, rinse immediately with plenty of water and seek medical advice.
- Avoid contact with skin.
- Do not breathe vapor.

# **NOTICE**

# Risk of property damage: Unsuitable lubricants

When using unsuitable lubricants, the vacuum system may be contaminated.

- Only use TEM oil 300 for lubricating.
- 1. Retract the respective detector.
- 2. Clean the rod with isopropanol with a clean, lint-free cloth.
- 3. Spread some drops of TEM oil 300 across the rod. Use a clean, lint-free cloth.

#### 8.7 Focused Ion Beam

### 8.7.1 Checking the Lifetime of the Ion Source

**Purpose** The ion source is a consumable that is used up during operation.

In order to keep track of the ion supply, the ion source lifetime needs to be checked regularly.

#### Info

When the lifetime of the ion source approaches 3000 µAh, contact the ZEISS service representative to have the ion source replaced.

- 1. In the **FIB Toolbar**, from the **FIB** drop-down list, select **FIB**.
  - → The **FIB** tab of the **FIB Control Panel** is displayed.
  - $\rightarrow$  The lifetime of the ion source is indicated as  $\mu$ Ah.
- 2. Check the lifetime of the ion source.

# 8.7.2 Regenerating the Ion Source by Heating

**Purpose** From time to time, the gallium emitter has to be regenerated by heating.

The heating procedure is used in following cases:

- If the suppressor voltage has reached its limits (i.e. 0 V or 2 kV) while a probe current of 2 µA cannot be maintained anymore
- If the ion source does not start emitting
- If the source is switched into Standby mode because the emission current exceeds the threshold defined in the SmartSEM Administrator in the Go to Standby if emission exceeds input field.

#### Info

Source heating can also be performed via Source Management. Source Management includes automatically triggered procedures to ensure an optimum performance of the ion source. These procedures are configured in the SmartSEM Administrator via FIB > FIB Source Management.

#### Safety Information

#### NOTICE

# Risk of property damage: Ion source

Danger of damaging the ion source due to overheating. Excessive filament heating may reduce source life.

Only heat as often as necessary.

- **Prerequisite** ✓ Requires the Supervisor privilege.
  - 1. In the Panel Configuration Bar, double-click FIB Ga Source Heating.
    - → The FIB Ga Source Heating window is displayed.
  - 2. Click Multi-Heat.
    - → An automatic heating routine is performed.
  - 3. If the ion source still does not start emitting, find a new extractor value. Refer to Manually Finding a New Extractor Value [ 107].

#### 8.7.3 Manually Finding a New Extractor Value

**Purpose** If emission still fails after performing the multi-heating routine (see *Regenerating the Ion Source by Heating* [▶ 106]), you have to find a new extractor value.

In a first step, you can use the automatic FIB extractor adjustment functions:

- You can use Source Management. Source Management includes automatically triggered procedures to ensure an optimum performance of the ion source. These procedures are configured in the SmartSEM Administrator via FIB > FIB Source Management.
- You can trigger the extractor adjustment via FIB Control Panel > FIB > Extr. Adjust.

If the automatic FIB extractor adjustment functions fail, you have to find a new extractor value manually.

- 1. In the FIB Toolbar, from the FIB drop-down list, select FIB.
  - → The **FIB** tab of the **FIB Control Panel** is displayed.
- 2. Click Standby.
  - → The FIB gun is set to **Standby** mode.
- 3. To disable the suppressor regulation, deactivate the **Regulate** checkbox.
- 4. Set the **FIB Suppressor Target** to 1200 V.
- 5. Select the **Options** tab.
- 6. Activate the **FIB Extractor Manual Override** checkbox.
- 7. Move the slider **FIB Manual Extractor Target** slowly until FIB emission starts.
- 8. Adjust the **FIB Manual Extractor Target** until emission is approximately 2 μA.
- 9. Leave the source in this condition for about 5 minutes, adjust the extractor voltage if necessary to keep the emission at  $2 \mu A$ .
- 10. Click Save Value.
- 11. Deactivate the **FIB Extractor Manual Override** checkbox.
- 12. Select the **FIB** tab.
- 13. To enable the suppressor regulation, activate the **Regulate** checkbox.

#### Info

During the process of finding a new extractor target, the FIB gun will be automatically switched to the **On** state.

# 9 Shutdown and Disposal

# 9.1 Putting the Microscope out of Operation

If the microscope will not be used for an extended period of time, e.g. several months, it should be put out of operation.

Contact your local ZEISS service representative to have the microscope put out of operation.

# 9.2 Transport and Storage

# **MARNING**

# Risk of injury: Tilting hazard when removing the microscope from the crate

When removing the microscope from the wooden crate, it can tilt and crush a person.

• Use a forklift to remove the microscope from the wooden crate.

# **!** CAUTION

# Risk of injury: Crushing hazard when lowering the microscope

The microscope and its components are heavy. When the load is lowered during transport and positioning, body parts can be crushed.

- Maintain a safe distance.
- Do not walk or place your hands or feet under the load while it is being lowered.
- Wear safety shoes and gloves.

# **A** CAUTION

# Risk of injury or property damage: GIS precursors

If a gas injection system (GIS) is used, the precursors may be explosive, reactive, toxic or irritant when they come into contact with the environment or a person.

- ▶ Do not remove or install a GIS reservoir. Contact your local ZEISS service representative to have a reservoir removed or installed.
- ▶ The microscope may only be shipped if all precursors have been removed.
- Precursors have to be shipped separately in a special transport container. For shipment always enclose a print-out of the respective material safety data sheet (MSDS).
- Store and transport precursors only within the prescribed temperature ranges.
- For further information, refer to the GIS instruction manual.

## **NOTICE**

## Risk of property damage: Damage during transport

Sensitive components of the microscope can get damaged during transport.

- ▶ The microscope may only be transported in air-suspended vehicles.
- Moving parts must be secured during transport to prevent them from slipping or tipping over.
- Install shock/tilt watches.
- ▶ Avoid rocking the crates back and forth.
- ▶ Devices for transporting the microscope must be rated to handle its full weight and dimensions. Note the weight information on the package and on the shipping document.
- Check that none of the items has been damaged during shipment.
- Otherwise contact your local ZEISS service representative.

#### **Packaging of the Microscope**

The microscope is delivered in two wooden crates:

Microscope plinth

Wrapped with recyclable polyethylene-foil and shipped in a reusable wooden crate.

Dimensions and weight of crate:

 $1550 \times 1550 \times 2200 \text{ mm}^3 \text{ (W} \times D \times H), appr. 1300 \text{ kg}$ 

Microscope console and accessories

Console, valve, damper, monitors, cables, pipes etc. are wrapped with recyclable polyethylene-foil or packed in separate cartons and shipped in a reusable wooden crate.

Dimensions and weight of crate:

 $1720 \times 1100 \times 980 \text{ mm}^3 \text{ (W} \times D \times H)$ , appr. 300 kg

#### **Guidelines for Unpacking the Microscope**



Due to the heavy weight of microscopes, a forklift has to be used to remove the microscopes from the wooden crate:

- The forklift used must have a sufficient load capacity.
- Refer to the weights of the microscope stated in this chapter.

### **Guidelines for Transporting the Unpacked Microscope**



A hand pallet truck has to be used to move the microscope:

Ensure all hallways and corners are wide enough to be passed with the hand pallet truck.

#### **Allowable Conditions during Storage and Transport**

The packed microscope has to be stored in a dry place.

Allowable temperatur	e during storage and transport:	
Microscope:	between -10 °C and +70 °C	

If a GIS system is part of the microscope, the GIS precursors have to be transported and stored within the prescribed temperature ranges.

Allowable temperature dur	ing storage and transport:	
Precursor:	Gold	−30 °C (at least < 8 °C)
	Platinum	< 5 °C
	XeF <sub>2</sub>	< 5 °C
	All other reservoirs are allowe without cooling. However, ZE reservoirs during transport.	d to be stored and transported ISS recommends to cool all

## 9.3 Disposal

## 9.3.1 Disposing of Solid Waste (Consumables)

The operator must ensure that solid waste (consumables) is disposed of and recycled in a responsible manner.

Description	Material	Disposal
Schottky field emitter	Tungsten, ceramics	Used up emitters may be returned to the emitter manufacturer.
Apertures	Platinum, iridium, gold	Very small amounts. May be disposed of in accordance with local/regional regulations.
Ion source (gallium)	Gallium	To be returned to ZEISS.
GIS Precursors	For information regarding the the instruction manual of the 0	disposal of precursors, refer to GIS.

## 9.3.2 Disposing of the Microscope

The operator must ensure that waste products are disposed of and recycled in a responsible manner.

Refer to EC directive 2012/19/EC on waste electrical and electronic equipment (WEEE).

The microscope consists of several modules. Be careful to separate the materials properly when you dispose of the microscope.

- Materials: e.g. metals, non-metals, composite materials, process materials
- Electronic scrap material: e.g. transformers, circuit boards, cables

Comply with national and regional waste disposal regulations.

# 10 Technical Data and Conformity

## **10.1 Product Specification**

## **Electron Optics**

Parameter	Description
Resolution	GEMINI II column in High Resolution configuration (max. probe current 40 nA)
	Optimum working distance
	Without using Tandem Decel:
	<ul> <li>0.9 nm at 15 kV</li> </ul>
	<ul><li>1.6 nm at 1 kV</li></ul>
	Including Tandem Decel option:
	<ul><li>1.4 nm at 1 kV</li></ul>
	GEMINI II column in High Current configuration (max. probe current 100 nA)
	Optimum working distance
	Without using Tandem Decel:
	<ul> <li>0.9 nm at 15 kV</li> </ul>
	<ul><li>1.8 nm at 1 kV</li></ul>
	Including Tandem Decel option:
	<ul><li>1.6 nm at 1 kV</li></ul>
Acceleration volt-	Range: 20 V to 30 kV
age	Adjustment: Continuously variable in 10 Volt steps
Probe current	High Resolution configuration: 10 pA to 40 nA
	High Current configuration: 10 pA to 100 nA
	Probe current regulation via a double condenser system
Magnification	Range: 12x to 2,000,000x referenced to Polaroid image format
Electron course	
Electron source	Filament: Schottky field emitter
Electron Source	Filament: Schottky field emitter  Automatic emitter run-up: Safe controlled run-up to the target emitter conditions
Objective lens	Automatic emitter run-up: Safe controlled run-up to the target
	Automatic emitter run-up: Safe controlled run-up to the target emitter conditions  Type: Patented GEMINI II electromagnetic/electrostatic objective lens system (68° conical final lens) with water cooling for best thermal sta-
Objective lens	Automatic emitter run-up: Safe controlled run-up to the target emitter conditions  Type: Patented GEMINI II electromagnetic/electrostatic objective lens system (68° conical final lens) with water cooling for best thermal stability and reproducibility  Working distance: Range from 1 to 50 mm, depending on accelera-
Objective lens	Automatic emitter run-up: Safe controlled run-up to the target emitter conditions  Type: Patented GEMINI II electromagnetic/electrostatic objective lens system (68° conical final lens) with water cooling for best thermal stability and reproducibility  Working distance: Range from 1 to 50 mm, depending on acceleration voltage  Focus compensation: Automatic compensation to minimize focus

Parameter	Description
	<b>Rotation compensation:</b> Automatic correction of apparent image rotation with changes in working distance
Beam shift	For precise adjustment of image position at high magnifications Width: 200 $\mu$ m ( $\pm 100~\mu$ m) at 20 kV and WD = 8.5 mm
Tandem decel (optional)	<b>Tandem decel module</b> to apply negative bias to the specimen. Bias voltage can be set to 1 kV, 2 kV, 3 kV, 5 kV and continuously varied between 50 V and 100 V in steps of 1 V.
	Airlock enabled specimen holder designed to ensure optimum electri-
	cal field geometry included

## **Focused Ion Beam Column**

Parameter	Description
Ion Source	Type: UHV, with gallium liquid metal ion source (Ga-LMIS)
	Source Life: 3000 hours at 1 $\mu A$ of emission current
	Isolation: Automatically controlled valve for source isolation
FIB resolution	3 nm at 30 kV
Probe current	1 pA to 100 nA
Magnification	300x to 500,000x
Acceleration Volt-	Range: 0.5 to 30 kV
age	Adjustment: Continuously variable in 10 Volt steps
Imaging/Pattern-	Maximum field of view: 580 × 580 μm
ing	User beam shift: ±15 μm
Dwell time	Minimum dwell time: 25 ns
	Maximum dwell time: 1 s
Lenses	Type: Two electrostatic lenses

## **Specimen Chamber and Stage**

Parameter	Description	
	Crossbeam 550	Crossbeam 550 L
Specimen chamber dimensions	<ul><li>330 mm inner diameter</li><li>270 mm height</li></ul>	<ul><li>520 mm inner diameter</li><li>307 mm height</li></ul>
Free accessory ports	18 for EDS, EBSD, SIMS, manipulators etc.	22 free ports for optional accessories such as load lock, STEM, 4QBSD, GIS, EDS, WDS, EBSD, CL, flood gun, cryo transfer, SIMS, manipulator, etc.

Parameter	Description	
	Crossbeam 550	Crossbeam 550 L
Analytical working distance	5 to 8.5 mm	
Coincidence point	5 mm (SEM), 12 mm (FIB)	
Column arrange- ment	The angle between electron-optica 54°.	al and focused ion beam-column is
Specimen stage Type: 6-axes motorized super-eucentric, controlled via the Smar user interface, operated by a dual joystick control box		
	Mounting: Drawer-type door	
	Movements:	
	■ X/Y = 100 mm	<ul><li>X/Y = 153 mm</li></ul>
	Z = 50 mm	Z = 50 mm
	• M = 13 mm	M = 20 mm
	Tilt = $-4^{\circ}$ to $70^{\circ}$	• Tilt = $-15^{\circ}$ to $70^{\circ}$
	<ul> <li>Rotation = 360° continuous</li> </ul>	<ul><li>Rotation = 360° continuous</li></ul>
	INFO: The movements may be reduced conditions, and accessories attached	
	Accessory ports: Two accessory points vided	ports on the stage door are pro-
	Specimen weight: Up to 0.5 kg	
	<b>Specimen current monitor</b> with touch alarm warning with on-scree	
	<b>Specimen mounts:</b> One carousel ameter stubs included in base tool holders available as option	
Plasma cleaner	Integrated plasma cleaner:	
(optional)	Chamber mounted plasma cleaner tamination from both specimen an control for user defined cleaning costarting the cleaning process	

## **Detection System**

Parameter	Description
Detection system	Detection system equipped for parallel detection and signal processing of multiple detector channels:
	<ul> <li>Up to 12 detector channels and up to 3 TV inputs</li> </ul>
	<ul> <li>Parallel detection, processing, and display of up to four channels possible</li> </ul>
	<ul> <li>2 signal detector inputs can be mixed for enhanced image information</li> </ul>
InLens detectors	InLens SE detector:

Parameter	Description
	High efficiency annular scintillator detector mounted in GEMINI col- umn with optically coupled photomultiplier.
-	InLens EsB detector (optional):
	Column-mounted high efficiency scintillator detector with optically coupled photomultiplier for detection of energy and angle selective backscattered electrons. Filtering grid adjustable from 0 V to $-1.5$ kV for contrast adjustment.
Chamber detectors	SE detector:
	Everhart-Thornley SE detector with optically coupled photomultiplier; collector bias adjustable from $-250$ to $+400$ V
-	SESI detector (optional):
	Combined Secondary Electron Secondary Ion (SESI) detector based on a scintillator photomultiplier system; easy change between secondary ion and secondary electron mode by converting the electrode voltage; replaces the SE detector
-	CL detector (optional):
	Cathodoluminiscence (CL) chamber detector
-	aSTEM detector (optional):
	Pneumatically retractable multi-mode annular Scanning Transmission Electron Microscopy (aSTEM) detector; enables bright field (BF), dark field (DF), and high angle annular dark field (HAADF) detection
_	aBSD/BSD detector (optional):
	Pneumatically retractable 5 or 6 segment multi-mode solid state BSE detector; enables materials contrast, crystal orientation, and topographic imaging
Chamber camera	Color CCD camera with white-light illumination and IR illumination
Specimen current monitor	6 range auto ranging for precise current measurement in the range of 1 pA to 10 $\mu\text{A}$

For more details, refer to the document Product Specification.

## **10.2 Installation Requirements**

For a complete list of the installation requirements, refer to the document Installation Requirements.

## **Location Requirements**

Parameter	Requirement
Installation site	Exclusively inside buildings
Recommended room size	Min. 4.0 m × 5.0 m × 2.3 m
Service area	Min. 1.0 m at each side
Entrance	Min. 1.1 m wide
Hallways	Min. 1.3 m wide

Parameter	Requirement
Corners	Min. 1.5 m wide
Transport ways	Free of staircases
Installation cate- gory	II
Floor stability	> 1000 kg/m <sup>2</sup>
Parameter	Requirement
Installation site	Exclusively inside buildings
Recommended room size	Min. 3.5 m × 5.0 m × 2.3 m
Service area	Min. 1.0 m at each side
Entrance	Min. 0.8 m wide
Hallways	Min. 1.0 m wide
Corners	Min. 1.2 m wide
Transport ways	Free of staircases
Installation cate- gory	II
Floor stability	$> 1000 \text{ kg/m}^2$
Parameter	Requirement
Parameter Installation site	Requirement Exclusively inside buildings
Installation site Recommended	Exclusively inside buildings
Installation site  Recommended room size	Exclusively inside buildings  Min. $3.6 \text{ m} \times 5.0 \text{ m} \times 2.3 \text{ m}$
Installation site  Recommended room size  Service area	Exclusively inside buildings  Min. $3.6 \text{ m} \times 5.0 \text{ m} \times 2.3 \text{ m}$ Min. $0.8 \text{ m}$ at each side
Installation site  Recommended room size  Service area  Entrance	Exclusively inside buildings  Min. $3.6 \text{ m} \times 5.0 \text{ m} \times 2.3 \text{ m}$ Min. $0.8 \text{ m}$ at each side  Min. $0.8 \text{ m}$ wide
Installation site  Recommended room size  Service area  Entrance  Hallways	Exclusively inside buildings  Min. 3.6 m × 5.0 m × 2.3 m  Min. 0.8 m at each side  Min. 0.8 m wide  Min. 1.0 m wide
Installation site  Recommended room size  Service area  Entrance  Hallways  Corners	Exclusively inside buildings  Min. 3.6 m × 5.0 m × 2.3 m  Min. 0.8 m at each side  Min. 0.8 m wide  Min. 1.0 m wide  Min. 1.2 m wide
Installation site  Recommended room size  Service area  Entrance  Hallways  Corners  Transport ways  Installation cate-	Exclusively inside buildings  Min. 3.6 m × 5.0 m × 2.3 m  Min. 0.8 m at each side  Min. 0.8 m wide  Min. 1.0 m wide  Min. 1.2 m wide  Free of staircases
Installation site  Recommended room size  Service area  Entrance  Hallways  Corners  Transport ways  Installation category	Exclusively inside buildings  Min. 3.6 m × 5.0 m × 2.3 m  Min. 0.8 m at each side  Min. 0.8 m wide  Min. 1.0 m wide  Min. 1.2 m wide  Free of staircases
Installation site  Recommended room size  Service area  Entrance  Hallways  Corners  Transport ways  Installation category  Floor stability	Exclusively inside buildings  Min. 3.6 m × 5.0 m × 2.3 m  Min. 0.8 m at each side  Min. 0.8 m wide  Min. 1.0 m wide  Min. 1.2 m wide  Free of staircases  II  > 1000 kg/m²
Installation site  Recommended room size  Service area  Entrance  Hallways  Corners  Transport ways  Installation category  Floor stability  Parameter	Exclusively inside buildings  Min. 3.6 m × 5.0 m × 2.3 m  Min. 0.8 m at each side  Min. 0.8 m wide  Min. 1.0 m wide  Min. 1.2 m wide  Free of staircases  II  > 1000 kg/m²  Requirement
Installation site  Recommended room size  Service area  Entrance  Hallways  Corners  Transport ways  Installation category  Floor stability  Parameter  Installation site  Recommended	Exclusively inside buildings  Min. 3.6 m × 5.0 m × 2.3 m  Min. 0.8 m at each side  Min. 0.8 m wide  Min. 1.0 m wide  Min. 1.2 m wide  Free of staircases  II  > 1000 kg/m²  Requirement  Exclusively inside buildings

Parameter	Requirement
Entrance	Min. 0.8 m wide
Hallways	Min. 1.0 m wide
Corners	Min. 1.2 m wide
Transport ways	Free of staircases
Installation cate- gory	II
Floor stability	> 1000 kg/m <sup>2</sup>

#### **Exhaust Line**

An exhaust line is required to remove the waste gas of the pre-vacuum pump and to transmit it to the outside.

If toxic chemicals or biological specimens are used an exhaust line is recommended to remove the waste gas of the pre-vacuum pump and to transmit it to the outside.

## **Electrical Supplies**

Parameter	Requirement
	·
Nominal AC volt- age	208–230 VAC (±10 %), L1/N(L2)/PE
	The provided electrical connection must be in accordance with the applicable electrical codes for the country of installation. In order to avoid disturbance from other installed machines, ZEISS recommends using a separate power connection to the main distribution panel.
Protection class	Class I
Nominal frequency	50–60 Hz
Momentary inter- ruption	Less than a half cycle
System connection	The microscope is delivered with a power cord
	3 × AWG10 UL-style (3 m long) and a CEE-connector (Type 32 A-6 h;
	200 to 230 V, 2P+PE). Alternatively the microscope can be installed directly to a switchable power distribution terminal which can be se-
	cured against accidental re-activation.
Power consump- tion	Max. 3.7 kVA, dependent on accessories
Maximum current	16 A
Circuit breaker (at house installation)	25 A (type K)
Ampere interrupt- ing capacity (AIC)	Min. 10,000 A rms
Protective ground	High leakage currents are present in the microscope. Therefore, the microscope has to be connected to an equipotential bonding bar. An exclusive grounding connection to earth must be provided, i.e. the grounding terminal must not be common to other electrical equipment. A grounding wire AWG10 is delivered with the microscope.  Cross section: > 4 mm <sup>2</sup>

Parameter	Requirement
	Ground resistance: $< 0.1 \Omega$
Parameter	Requirement
Nominal AC voltage	230 V <sub>AC</sub> 1/N/PE or 208 V <sub>AC</sub> 2/PE The provided electrical connection must be in accordance with the applicable electrical codes for the country of installation. In order to avoid disturbance from other installed machines, ZEISS recommends using a separate power connection to the main distribution panel.
Protection class	Class I
Nominal frequency	50-60 Hz
Momentary inter- ruption	Less than a half cycle
System connection	The microscope is delivered with a 3 m long power cord that is equipped with a 200–250 V <sub>AC</sub> CEE MALE PLUG 2P3W 6h 16A (blue) according to IEC 60309.  The supplied connection cable must not be replaced with another one. Otherwise, the conformity with listed standards becomes invalid.
	The building installation should provide the corresponding 200–250 $V_{AC}$ CEE FEMALE RECEPTACLE 2P3W 6h 16A (blue) with the correct wiring 1/N/PE or 2/PE and the desired approvals of the country used.
	To avoid disturbance from other installed machines Carl Zeiss Microscopy recommends to use a separate power connection to the main distribution panel.
Power consump- tion	Max. 3 kVA, dependent on accessories
Circuit breaker (at house installation)	16 A Type C
Ampere interrupt- ing capacity (AIC)	Min. 10,000 A <sub>rms</sub>
Protective ground	High leakage currents are present in the microscope. Therefore, the microscope has to be connected to a separate protective ground.  An exclusive grounding connection to earth must be provided as part of the building installation, i.e. a grounding screw terminal (Ø 8 mm) which is directly connected to the PE of the FEMALE RECEPTACLE as short as possible. (see picture)  This grounding connection must not be common to other electrical equipment.

## Requirement **Parameter** CEE **FEMALE** RECEPTACLE from Branch Circuit Breaker Screw Terminal Ø8 mm A grounding wire AWG10 ( $\geq$ 5 m) is delivered with the microscope. It serves as connection between the grounding screw terminal (Ø 8 mm) and the microscope (Ø 6 mm). Cross section: Min. AWG10 (between grounding screw terminal and PE of the CEE FEMALE RECEPTACLE)<sup>2</sup>

Parameter	Requirement
Nominal AC voltage	120 $V_{AC}$ (single phase) or 230 $V_{AC}$ (single phase)
	The provided electrical connection must be in accordance with the applicable electrical codes for the country of installation. In order to avoid disturbance from other installed machines, ZEISS recommends using a separate power connection to the main distribution panel.
	Details see System Connection
Protection class	Class I
Nominal frequency	50-60 Hz
Momentary inter- ruption	Less than a half cycle
System connection	The microscope is delivered with a power cord 3 m long equipped with a CEE plug 1/N/PE according to IEC 60309 depending on the customers site supply: either for 120 $V_{AC}$ a CEE MALE PLUG 2P3W 4h 20A (yellow) or for 230 $V_{AC}$ a CEE MALE PLUG 2P3W 6h 16A (blue).
	The building installation should provide the corresponding CEE socket 1/N/PE with desired approvals of the country used: either for 120 $\rm V_{AC}$ a CEE FEMALE RECEPTACLE 2P3W 4h 20A (yellow) or for 230 $\rm V_{AC}$ a CEE FEMALE RECEPTACLE 2P3W 6h 16A (blue).
	To avoid disturbance from other installed machines Carl Zeiss Microscopy recommends to use a separate power connection to the main distribution panel.
Power consump- tion	Max. 3 kVA, dependent on accessories
Circuit breaker (at house installation)	16 A Type C
Ampere interrupt- ing capacity (AIC)	Min. 10,000 A <sub>rms</sub>

## Requirement **Parameter Protective ground** High leakage currents are present in the microscope. Therefore, the microscope has to be connected to a separate protective ground. An exclusive grounding connection to earth must be provided as part of the building installation, i.e. a grounding screw terminal (Ø 8 mm) which is directly connected to the PE of the FEMALE RECEPTACLE as short as possible. This grounding connection must not be common to other electrical equipment. CEE **FEMALE** RECEPTACLE from Branch Circuit PE Breaker Screw Terminal Ø8 mm A grounding wire AWG10 ( $\geq 5$ m) is delivered with the microscope. It serves as connection between the grounding screw terminal (Ø 8 mm) and the microscope (Ø 6 mm). Cross section: Min. AWG10 (between grounding screw terminal and PE of the CEE FEMALE RECEPTACLE)<sup>2</sup>

## **Cooling Water**

Major components of the microscope such as electron-optic lenses, parts of the electronics and the turbo molecular pump are water-cooled. Any cooling solution has to fulfil the following requirements.

Parameter	Requirement
Water flow rate	60–70 l/h
Pressure	Adjustable up to 3 bar
Water tempera- ture	20–22 °C
Stability	0.5 °C/10 min
Heat dissipation	1 kW
Connection hose	6 mm inside diameter. Two pieces 10 m each are delivered.
Parameter	Requirement
Water flow rate	> 1.5 l/min
Pressure	2–3 bar
Water tempera-	18–22 °C

Parameter	Requirement
Stability	0.5 °C/10 min
Heat dissipation	1 kW
Connection hose	8 mm inside diameter. One 25 m roll is delivered with the microscope.
Instrument con- nection	Quick exchange connectors. Two are delivered with the microscope.

#### Nitrogen

Gaseous dry nitrogen is used to vent the specimen chamber during specimen exchange. The nitrogen can be taken either from a gas cylinder or from an in-house supply system.

The connection must be equipped with an appropriate pressure reducer and a shut-off valve that is secured against accidental re-activation.

Parameter	Requirement
Flow rate	Approx. 40 I/min for ventilation of specimen chamber with chamber door open
Pressure	0.30–0.35 MPa (3.0–3.5 bar)
Quality	4.6 with nitrogen content > 99.996 %
Connection hose	6 mm inside diameter. 10 m are delivered with the microscope.
Davamatav	Deminerant
Parameter	Requirement
Flow rate	Approx. 3 I/min for ventilation of specimen chamber with chamber door open
	Approx. 3 l/min for ventilation of specimen chamber with chamber
Flow rate	Approx. 3 l/min for ventilation of specimen chamber with chamber door open
Flow rate Pressure	Approx. 3 l/min for ventilation of specimen chamber with chamber door open  0.2–3.3 bar

## **Compressed Air**

Compressed air is used to operate several valves and the auto leveling system.

The necessary compressed air can be either generated by a compressor (part no. 345596-0000-000) or taken from a gas cylinder or from an in-house supply system.

The connection must be equipped with an appropriate pressure reducer and a shut-off valve that can be secured against accidental re-activation.

Parameter	Requirement
Typical flow rate	Approx. 12 l/min at 0.6 MPa pressure during air leveling system inflation
Pressure	0.6–0.8 MPa (6–8 bar)
Quality	Oil-free
Connection hose	6 mm inside diameter. 10 m are delivered with the microscope.

Parameter	Requirement
Typical flow rate	Less than 1 I/min during normal operation
Pressure	0.6–0.8 MPa (6–8 bar)
Quality	Oil-free
Connection hose	4 mm inside diameter. 10 m of pipe are delivered with the microscope.
Instrument con- nection	Quick exchange connector. One is delivered with the microscope.  INFO: Due to acoustic noise and vibrations the compressor – if used – should be installed in a separate room.

## **Environmental Requirements**

Environmental Requirements		
Parameter	Requirement	
Ambient tempera- ture	Appr. 21±4 °C	
Stability of ambi- ent temperature	0.5 °C/h	
For long-running experiments: Long-term stability of ambient tem- perature	2 °C/24 h	
Relative humidity	Less than 65 %	
Altitude	Max. 2000 m above sea level to guarantee an undisturbed operation	
Pollution degree	2	
Electrical field	The microscope is a class A device (industrial). The microscope is designed to operate in a controlled electromagnetic environment. This means that devices with RF transmitters such as mobile phones or DECT phones must not be used in close proximity.	
Vibrations	Up to 10 Hz: less than 5 μm/s	
	10–60 Hz: less than 10 μm/s	
	Above 60 Hz: less than 14 μm/s	
Magnetic stray fields	Measured in time domain and at specimen chamber height (1.0–1.5 m).	
	DC component: 0.5 mG / 5 min or less	
	AC component: less than 1 mG peak to peak between 10 Hz and 1 kHz	
Acoustic noise	Up to 120 Hz: less than 52 dB	
	120–450 Hz: less than 43 dB	
	Above 450 Hz: less than 47 dB	
Parameter	Requirement	
Ambient tempera-	Appr. 21±4 °C	

Parameter	Requirement
Stability of ambi- ent temperature	0.5 °C/h
For long-running experiments: Long-term stability of ambient temperature	2 °C/24 h
Relative humidity	Less than 65 %
Altitude	Max. 2000 m above sea level to guarantee an undisturbed operation
Pollution degree	2
Electrical field	The microscope is a class A device (industrial). The microscope is designed to operate in a controlled electromagnetic environment. This means that devices with RF transmitters such as mobile phones or DECT phones must not be used in close proximity.
Vibrations	Horizontal vibrations (in x/y-direction)
	Up to 10 Hz: less than 5 μm/s
	10–60 Hz: less than 10 μm/s
	Above 60 Hz: less than 14 μm/s
	Vertical vibrations (in z-direction)
	Up to 10 Hz: less than 4 μm/s
	10–60 Hz: less than 14 μm/s
	Above 60 Hz: less than 20 μm/s
Magnetic stray fields	Measured in time domain and at specimen chamber height (1.0–1.5 m).
	DC component: 0.5 mG / 5 min or less
	AC component: less than 1 mG peak to peak between 10 Hz and 1 kHz
Acoustic noise	Up to 120 Hz: less than 52 dB
	120–450 Hz: less than 43 dB
	Above 450 Hz: less than 47 dB
Parameter	Requirement
Ambient tempera- ture	Appr. 21±4 °C
Stability of ambient temperature	0.5 °C/h
For long-running experiments: Long-term stability of ambient temperature	2 °C/24 h
Relative humidity	Less than 65 %
Altitude	Max. 2000 m above sea level to guarantee an undisturbed operation
Aititude	Max. 2000 in above sea level to guarantee an analstarbea operation

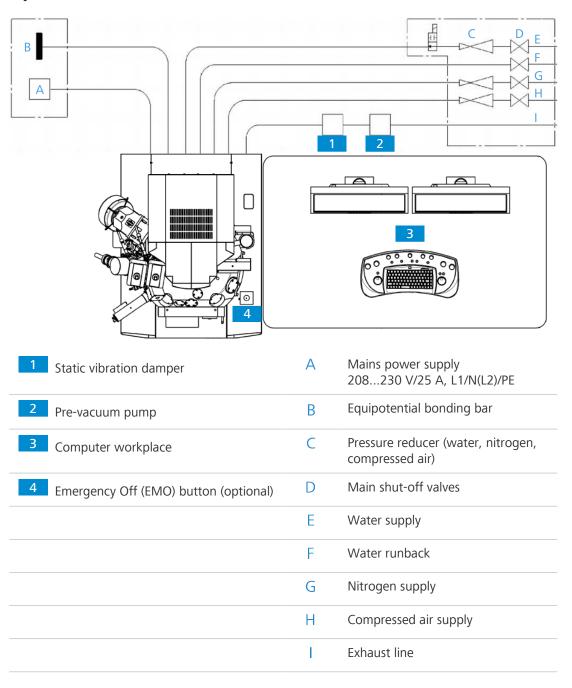
Parameter	Requirement
Pollution degree	2
Electrical field	The microscope is a class A device (industrial). The microscope is designed to operate in a controlled electromagnetic environment. This means that devices with RF transmitters such as mobile phones or DECT phones must not be used in close proximity.
Vibrations	Horizontal vibrations (in x/y-direction) Up to 10 Hz: less than 0.04 mm/s 10–20 Hz: less than 0.17 mm/s 20–70 Hz: less than 0.30 mm/s Above 70 Hz: less than 20 mm/s Vertical vibrations (in z-direction) Up to 8 Hz: less than 0.03 mm/s 8–45 Hz: less than 0.15 mm/s Above 45 Hz: less than 2.00 mm/s
Magnetic stray fields	Less than 3 mG peak to peak between 10 Hz and 1 kHz (Sigma 300) Less than 1 mG peak to peak between 10 Hz and 1 kHz (Sigma 500)
Acoustic noise	Sigma 300: Less than 53 dB for frequencies up to 200 Hz Less than 42 dB for frequencies from 200 up to 300 Hz Less than 50 dB for frequencies higher than 300 Hz Sigma 500: Less than 50 dB for frequencies up to 200 Hz Less than 40 dB for frequencies from 200 up to 400 Hz Less than 45 dB for frequencies higher than 400 Hz
Parameter	Requirement
Ambient temperature	20-30 °C It is recommended that for operator comfort the room temperature is maintained between 22 °C and 24 °C.
Stability of ambi- ent temperature	0.5 °C/h
For long-running experiments: Long-term stability of ambient tem- perature	2 °C/24 h
Relative humidity	Less than 65 %
Altitude	Max. 2000 m above sea level to guarantee an undisturbed operation
Pollution degree	2
Electrical field	The microscope is a class A device (industrial). The microscope is designed to operate in a controlled electromagnetic environment. This means that devices with RF transmitters such as mobile phones or DECT phones must not be used in close proximity.
C C	om 550   on-IIS   Poy 2   240500-9122-000

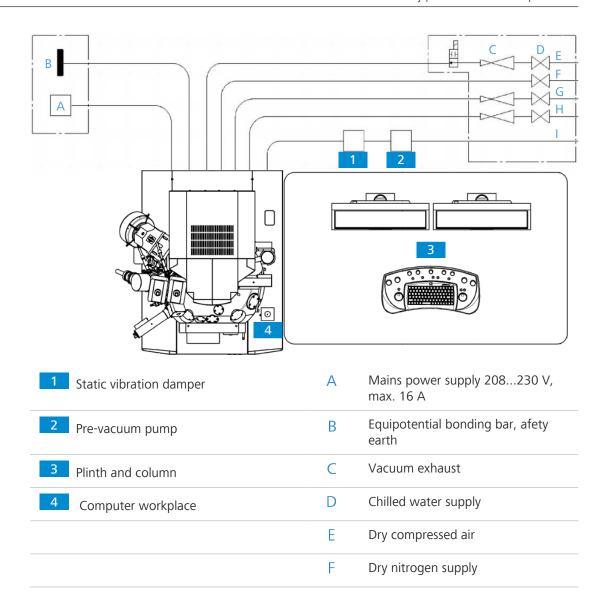
Requirement

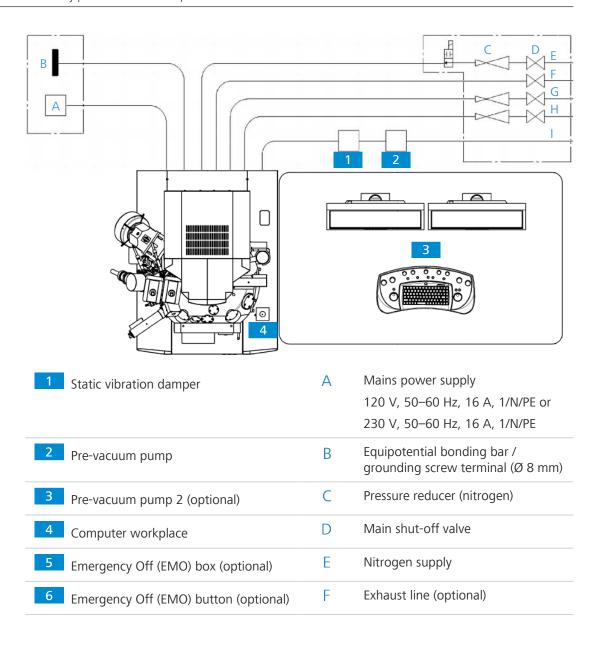
**Parameter** 

Parameter	Requirement
Vibrations	Less than 6 $\mu$ m/sec rms from 0–30 Hz Less than 12 $\mu$ m/sec rms above 30 Hz
Magnetic stray fields	Max. $3 \times 10^{-7}$ T (peak to peak) = 3 mG (peak to peak)
Acoustic noise	Less than 53 dB for frequencies up to 200 Hz Less than 42 dB for frequencies from 200 up to 300 Hz Less than 50 dB for frequencies higher than 300 Hz

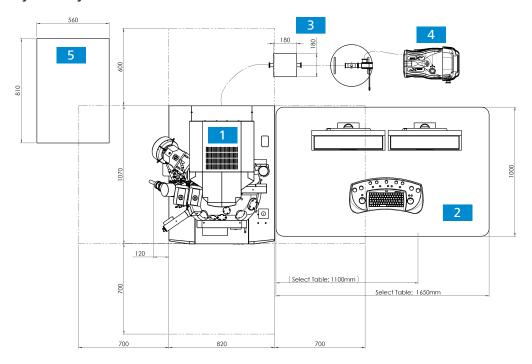
## 10.2.1 Layout and Connections







## 10.2.2 System Layout



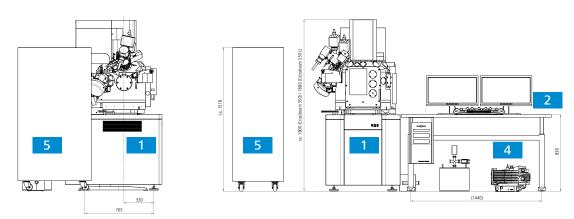


Fig. 37: System layout

- 1 Plinth + column + Ion-sculptor FIB (+ 200 mm airlock)
- 2 Table + PC
- 3 Static damping block
- 4 Pre-vacuum pump
- 5 FIB rack

Description	Size (mm) appr.	Distribution of load (kg)	Footprints
Plinth + column + Ion-sculptor FIB	940 × 1070 × 1800	4 × 250	4 × Ø 80 mm
Plinth + column + Ion-sculptor FIB + 200 mm airlock	1080 × 1070 × 1800	4 × 260	4 × Ø 80 mm
Table + PC	1650 × 1000 × 838 or 1100 × 1000 × 838	4 × 24.3	4 × Ø 50 mm

Description	Size (mm) appr.	Distribution of load (kg)	Footprints
Static damping block	180 × 180 × 160	1 × 12.0	180 mm × 180 mm
Pre-vacuum pump	432 × 265 × 295	1 × 24.5	200 mm × 180 mm
FIB rack	560 × 810 × 1600	4 × 50	on wheels
Chiller (optional, water- or air-cooled)*	530 × 640 × 740	4 × 22.5	on wheels
Compressor*	281 × 139 × 239	1 × 25.0	281 mm × 139 mm

<sup>\*</sup>Actual measurements are country dependent (different manufacturers).

Description	Size (mm) appr.	Distribution of load (kg)	Footprints
Plinth + column + Ion-sculptor FIB	$940 \times 1070 \times 1800$ (Crossbeam 550)	4 × 250	4 × Ø 80 mm
	$940 \times 1070 \times 1880$ (Crossbeam 550 L)	4 × 297.5	
Plinth + column + Ion-sculptor FIB + 200 mm airlock	1080 × 1070 × 1800 (Crossbeam 550)	4 × 260	4 × Ø 80 mm
	$1080 \times 1070 \times 1880$ (Crossbeam 550 L)	4 × 305	
Table + PC	1650 × 1000 × 838	4 × 24.3	4 × Ø 50 mm
	or		
	1100 × 1000 × 838		
Static damping block	180 × 180 × 160	1 × 12.0	180 mm × 180 mm
Pre-vacuum pump	432 × 265 × 295	1 × 24.5	200 mm × 180 mm
FIB rack	560 × 810 × 1600	4 × 50	on wheels
Chiller (optional, water- or air-cooled)*	530 × 640 × 740	4 × 22.5	on wheels
Compressor*	281 × 139 × 239	1 × 25.0	281 mm × 139 mm
*Actual measurements are country dependent (different manufacturers)			

<sup>\*</sup>Actual measurements are country dependent (different manufacturers).

## 10.3 Declaration of Conformity

**Denomination** Focused Ion Beam - Scanning Electron Microscope (FIB-SEM)

Model Crossbeam 550/550L

Manufacturer Carl Zeiss Microscopy GmbH

Carl-Zeiss-Str. 22 73447 Oberkochen Germany

We declare under our sole responsibility that the above machinery and the optional accessories fulfil all the relevant provisions of the following EC Directives:

- 2006/42/EC Machinery Directive
- 2014/30/EU Electromagnetic Compatibility

Applied harmonized standards:

- EN ISO 12100:2010 Safety of machinery General principles for design Risk assessment and risk reduction
- EN ISO 13849-1:2008 Safety of machinery Safety related parts of control systems –
   Part 1: General principles for design
- EN 60204-1:2006 Safety of machinery Electrical equipment of machines Part 1: General requirements
- EN 61010-1:2010 Safety requirements for electrical equipment for measurement, control, and laboratory use
- EN 61326-1:2013 Electrical equipment for measurement, control and laboratory use EMC requirements Part 1: General requirements

**CE Marking** The CE conformity marking is located on the type plate of the machinery or the optional accessory, respectively.

Unauthorized modifications of the machinery or the optional accessory will cancel this declaration.

## 11 Parts and Tools

## **NOTICE**

## Risk of property damage: Spare parts and consumables

Using spare parts or consumables that are not provided by ZEISS can lead to property damage.

- Only genuine spare parts and consumables supplied by ZEISS are to be used in servicing the microscope.
- Contact your ZEISS service representative for information regarding how to order spare parts and consumables.
- ▶ Unless otherwise authorized by ZEISS, all spare parts and consumables must be installed by a ZEISS service representative.

## 11.1 Consumables

Required Parts/Tools	Part Number
Schottky field emitter (gun) by DENKA	000000-0302-460
Aperture (single hole), 35 $\mu m$ thin film	348520-0229-000
Anode aperture, 55 $\mu$ m (40 nA High Resolution configuration)	348520-0621-000
Anode aperture, 90 µm (100 nA High Current configuration)	348520-0580-001
Extractor aperture	348520-0097-001
Anode aluminum seal	348520-0266-001
Copper seal gun head (single use)	000000-0546-290
Tip seal for pre-vacuum pump BOC Edwards XDS 10	000000-0113-989
Scintillator for SE detector	348306-8142-000
Ion source (gallium)	360100-0000-540
With GIS upgrade: Precursors	On request

## 11.2 Spare Parts

Required Parts/Tools	Part Number
Chamber door O-ring	000000-0476-960

## 11.3 Tools and Accessories

Required Parts/Tools	Part Number
Faraday cup	348342-8055-000
3 mm Allen key	000000-0015-247

Part Number
000000-0151-883
-
Refer to specimen holder catalog.
-
-
-
-

Index ZEISS

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